

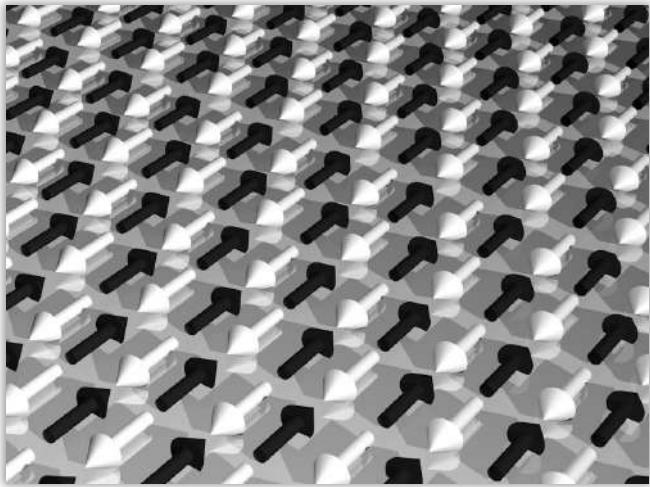
Antiferromagnetic Spintronics

Jean-Yves Chauleau

Service de Physique de l'Etat Condensé, CEA Saclay, UMR CNRS 3680



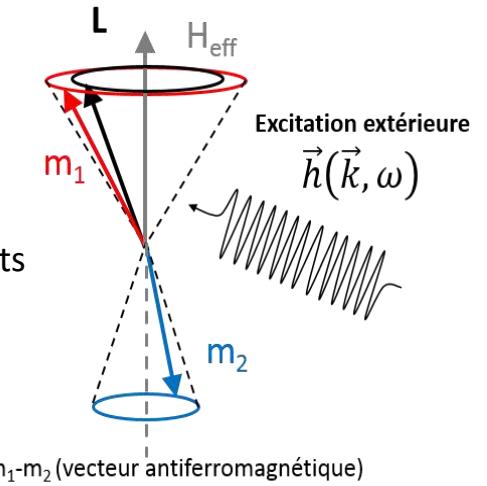
Antiferromagnet



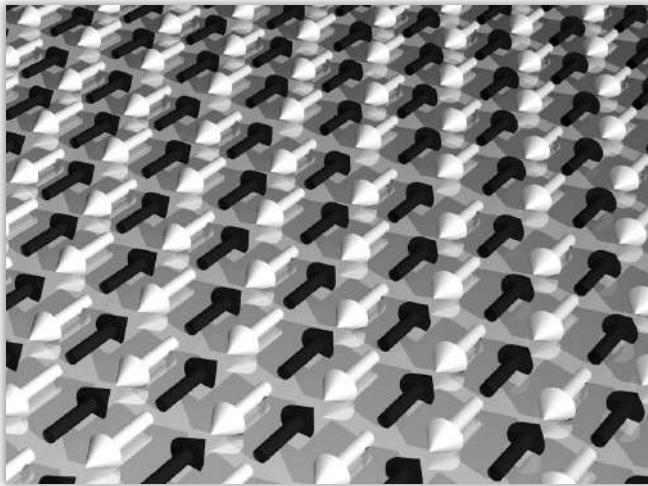
“Antiparallel arrangement of spins”

- No net magnetization / No magnetic stray field
- Large majority of magnetic materials are antiferromagnets (metals/ insulators/ with multifunctionnal abilities...)

- THz magnetic response
- Picosecond manipulation of the antiferromagnetic order

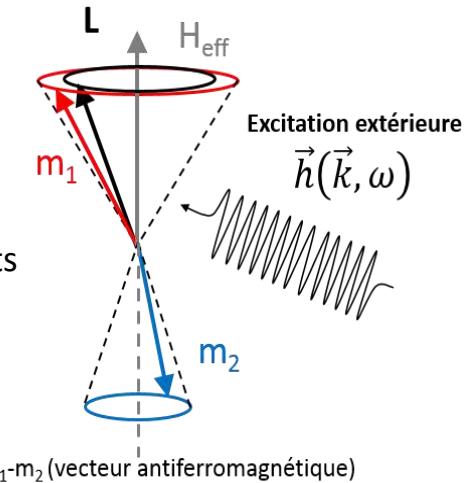


Antiferromagnet

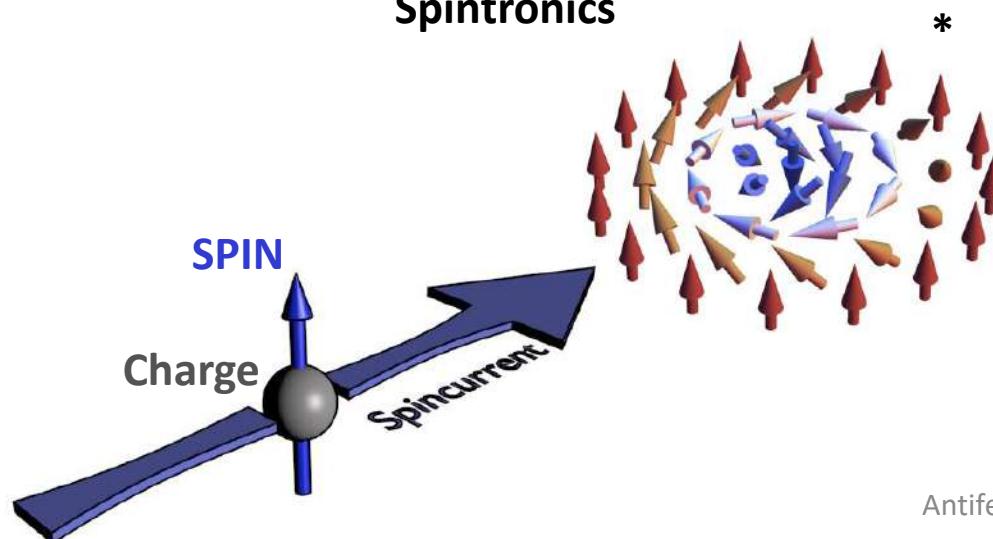


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Spintronics

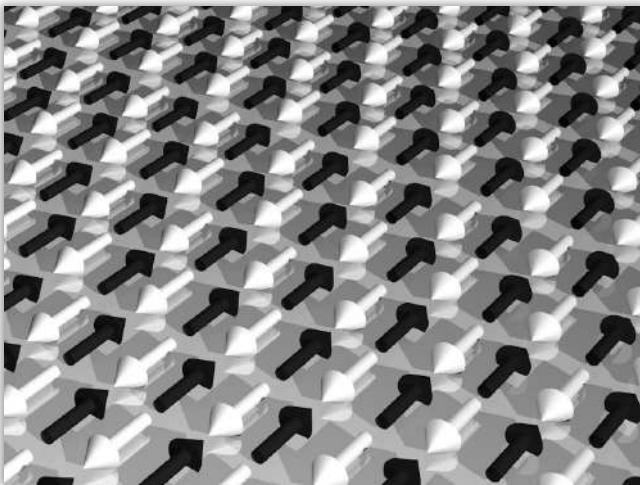


"Interplay between spincurrents and magnetic textures"

- Influence of magnetic textures upon electrical properties
- Generation / Transport / Detection of spincurrents
- Manipulation of magnetic objects using spincurrents (*spin transfer torque, spin-orbit torques...*)

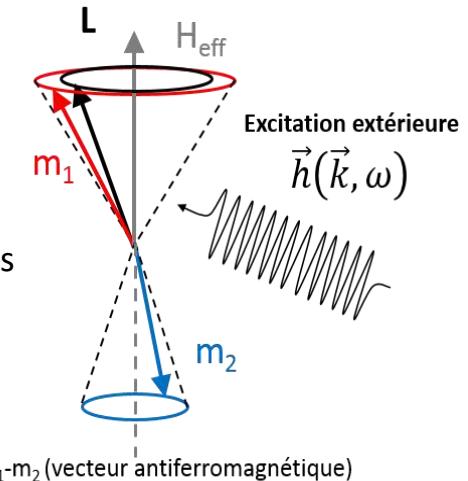
Antiferromagnetic Spintronics

Antiferromagnet

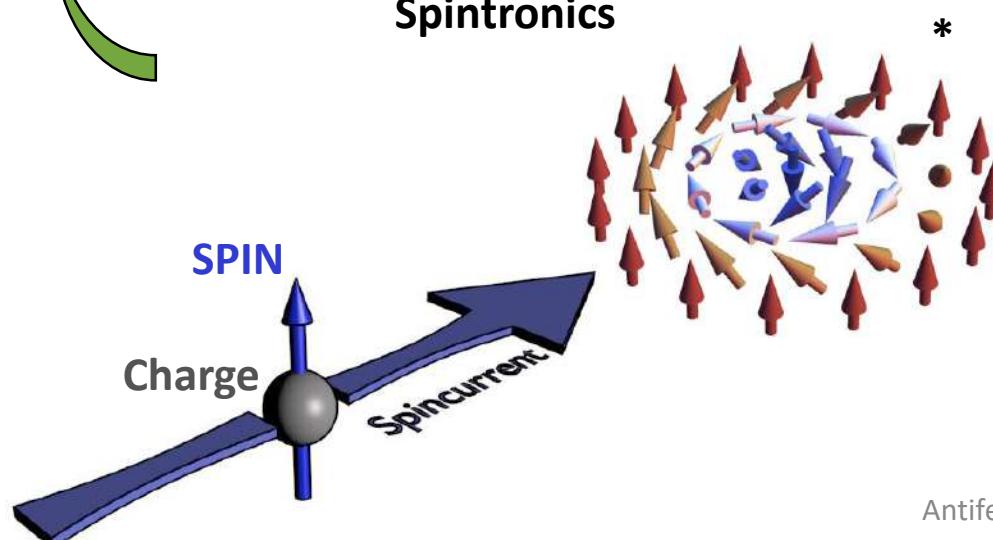


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Spintronics



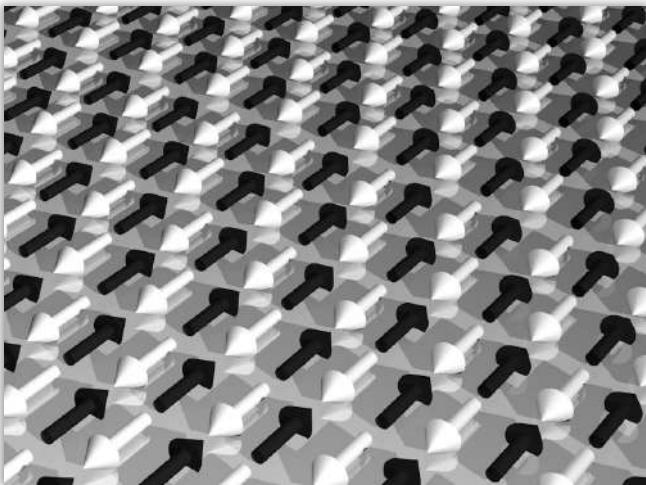
"Interplay between spincurrents and magnetic textures"

- Influence of magnetic textures upon electrical properties
- Generation / Transport / Detection of spincurrents
- Manipulation of magnetic objects using spincurrents (*spin transfer torque, spin-orbit torques...*)

... Works with/for antiferromagnets !!

Antiferromagnetic Spintronics

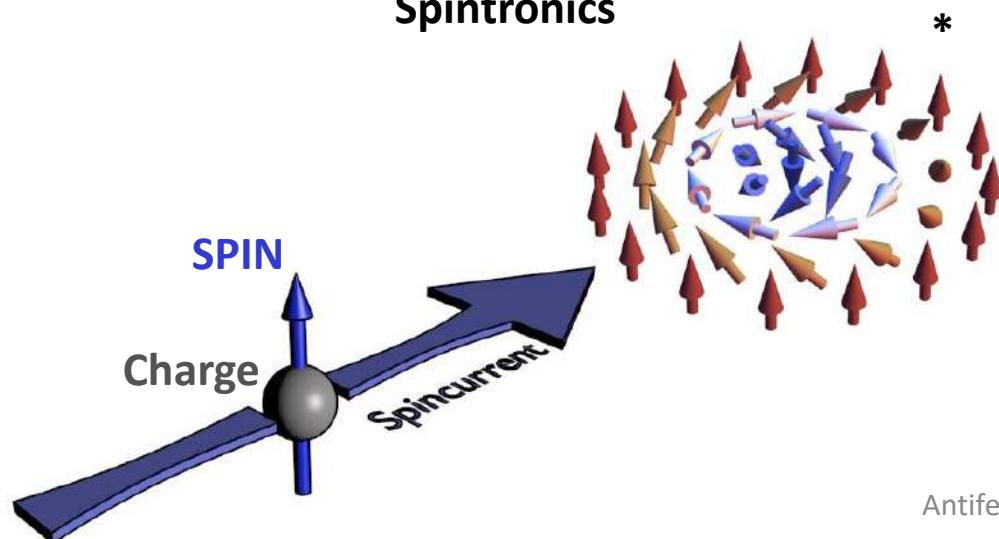
Antiferromagnet



Outline :

1. Generalities about Antiferromagnets
2. Antiferromagnetic dynamics & ultrafast THz capabilities
3. Spincurrents and antiferromagnets
 - a) Transport
 - b) Manipulation

Spintronics

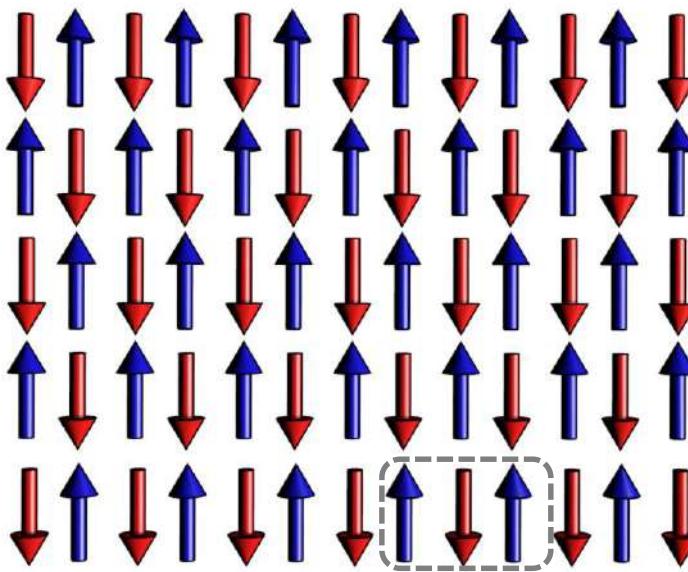


Antiferromagnetic Spintronics - ISOE2019 Chauleau

*From Science 336, 198 (2012)

Generalities:

"Antiparallel arrangement of spins"



➤ Predicated by Louis Néel in 1948

Ann. Phys., **12**, 137 (1948)

PROPRIÉTÉS MAGNÉTIQUES DES FERRITES; FERRIMAGNETISME ET ANTIFERROMAGNETISME

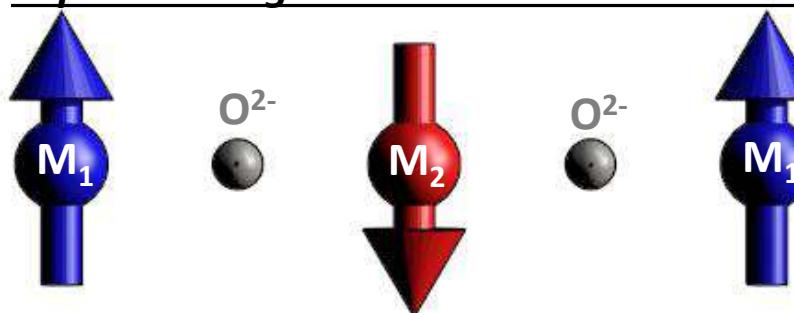
Par M. LOUIS NÉEL,

Professeur à la Faculté des Sciences de Grenoble.



Picture from www.nobelprize.org

Superexchange: main mechanism in oxides



Anderson *Physical Review* **79** 350 (1950)
Goodenough *Physical Review* **100** 564 (1955)
Kanamori *J. Phys. Chem. Solids* **10** 87 (1959)

➤ Negative exchange integral ($\mathfrak{J}_{ij} < 0$),
spin antiparallel alignment is favored

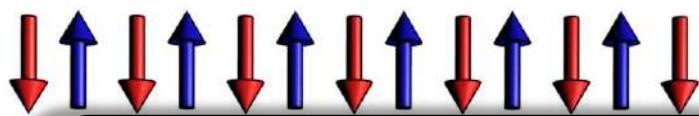
$$\mathcal{H}_{ex} = - \sum_{i,j} \mathfrak{J}_{ij} \mathbf{S}_i \cdot \mathbf{S}_j$$

➤ Antiferromagnets represent a large
majority of magnetic materials

Generalities:

"Antiparallel arrangement of spins"

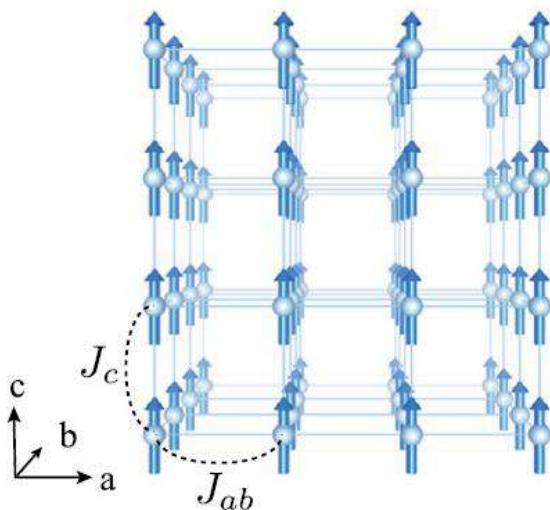
- The various possibilities for spin arrangement of 3D antiferromagnetic textures:



Ferromagnet

$$\mathbf{k} = (000)$$

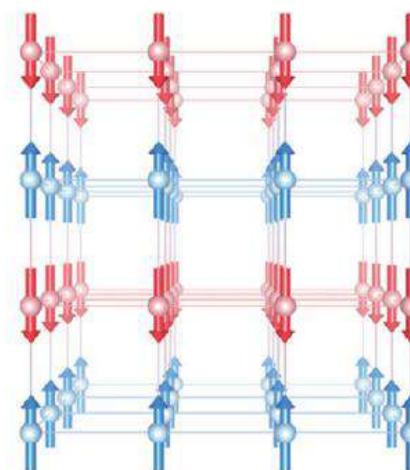
$$(J_{ab} > 0, J_c > 0)$$



A-type antiferromagnet

$$\mathbf{k} = (00\pi)$$

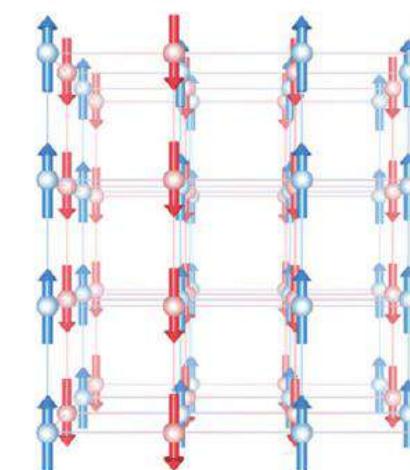
$$(J_{ab} > 0, J_c < 0)$$



C-type antiferromagnet

$$\mathbf{k} = (\pi\pi 0)$$

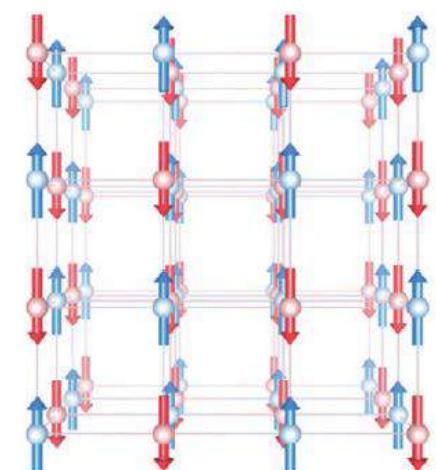
$$(J_{ab} < 0, J_c > 0)$$



G-type antiferromagnet

$$\mathbf{k} = (\pi\pi\pi)$$

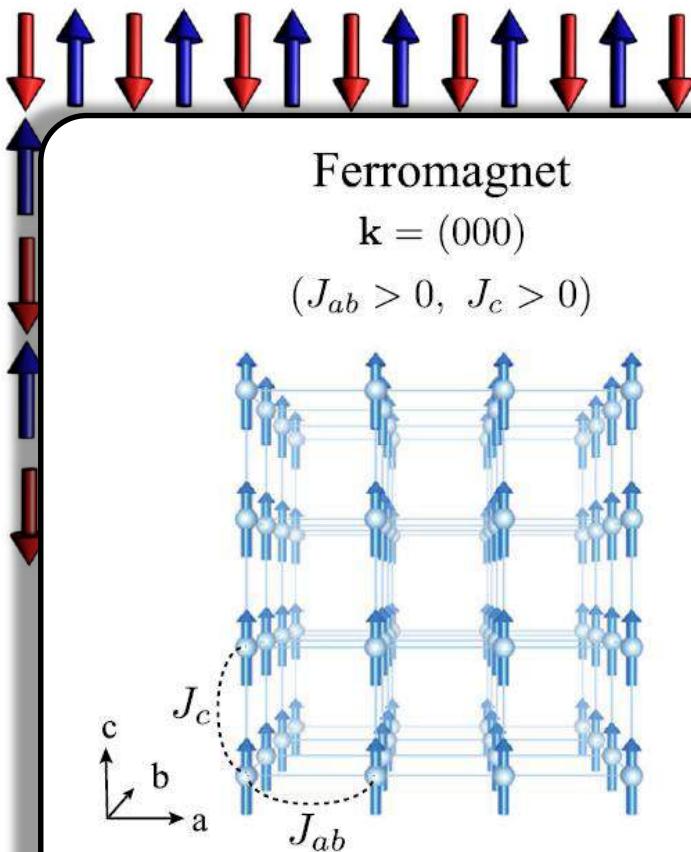
$$(J_{ab} < 0, J_c < 0)$$



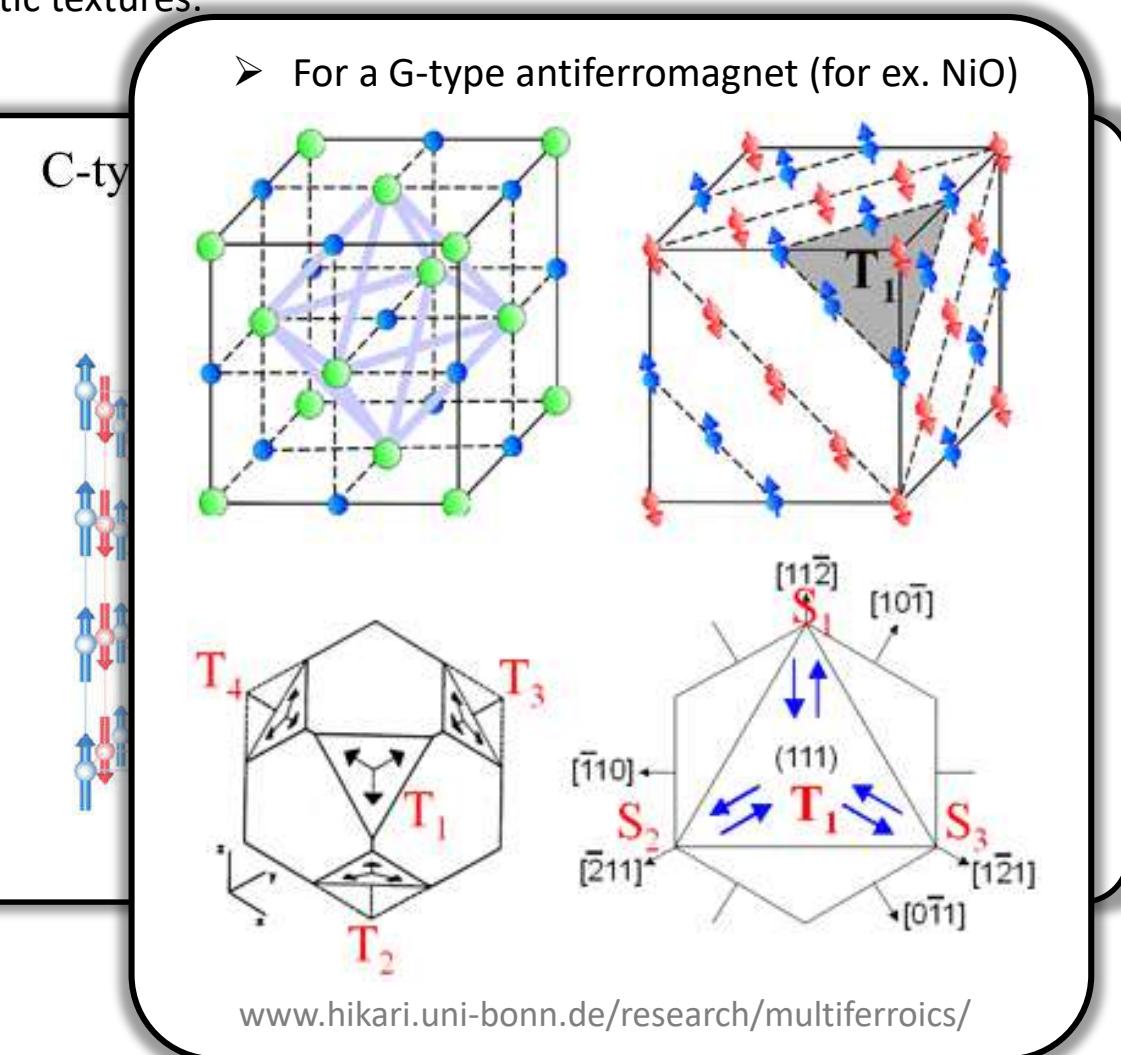
From Tamura et al. *J. Appl. Phys.*, **116**, 053908 (2014)

Generalities:

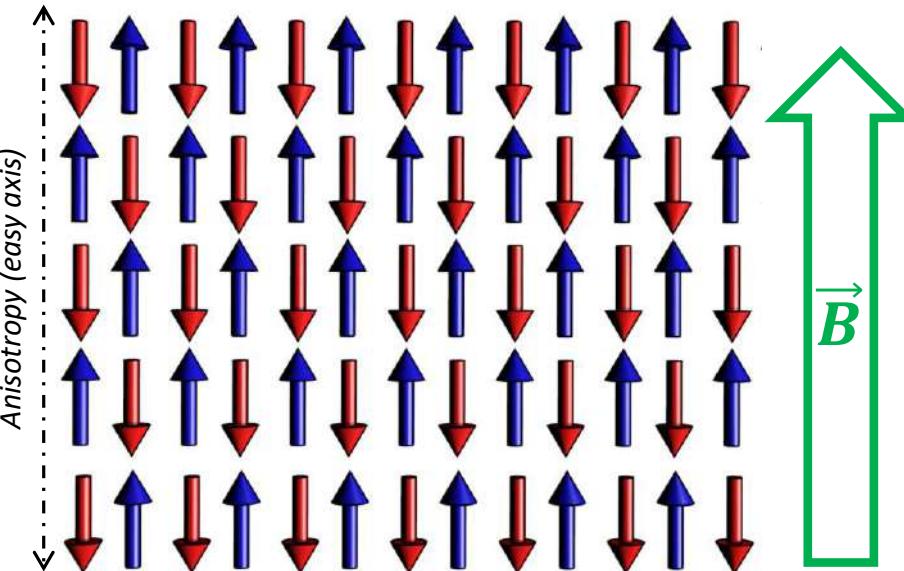
"Antiparallel arrangement of spins"



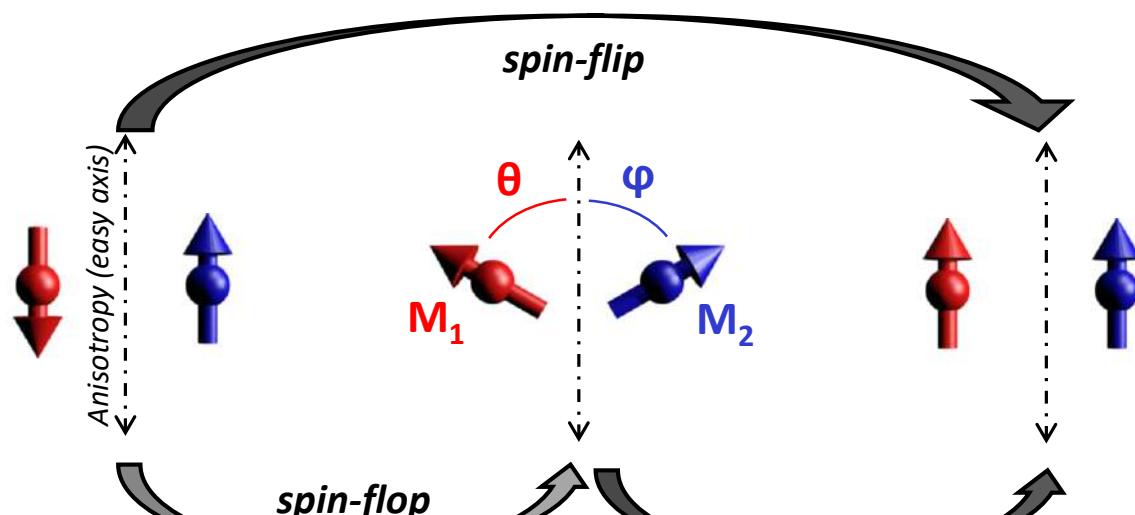
- The various possibilities for spin arrangement of 3D antiferromagnetic textures:



Generalities: Spin-flop (and Spin-flip) transitions



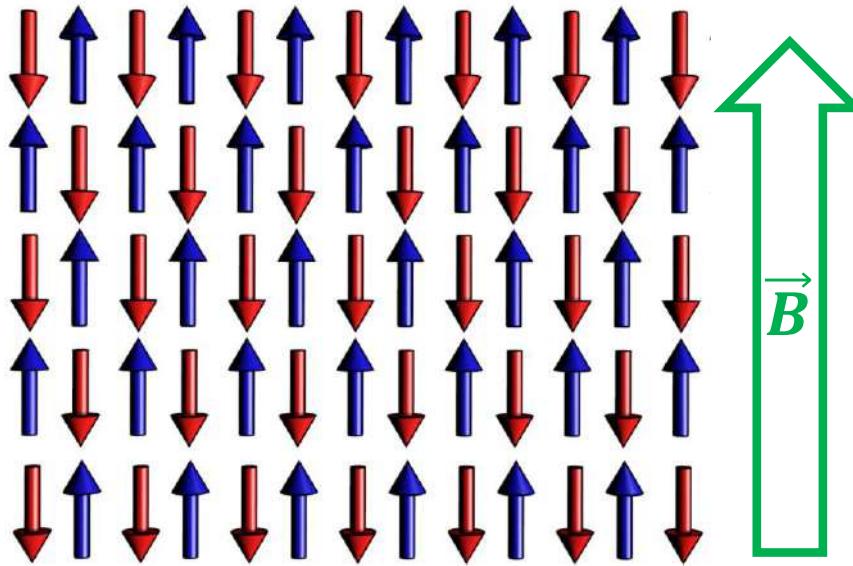
- **Magnetic fields (\vec{B})** : conventional way to act on magnetic textures
- Because of the absence of net magnetization, \vec{B} not “efficient” on AF textures \Longrightarrow **spin-flop and spin-flip transitions**



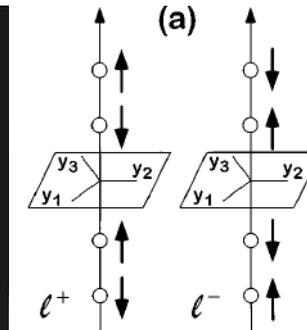
- **Magnetic energy:** E_{mag}

$$E_{mag} = \underbrace{\frac{|J|}{2} M^2}_{\text{Exchange}} \cos(\theta + \varphi) - \underbrace{MB}_{\text{Zeeman}} (\cos \theta + \cos \varphi) + \underbrace{\frac{K}{2} (\sin^2 \theta + \sin^2 \varphi)}_{\text{Anisotropy}}$$

Generalities: Spin-flop (and Spin-flip) transitions



- **Magnetic fields (\vec{B})** : conventional way to act on magnetic textures
- Because of the absence of net magnetization, \vec{B} not “efficient” on AF textures \Longrightarrow **spin-flop and spin-flip transitions**
- Example: Cr_2O_3



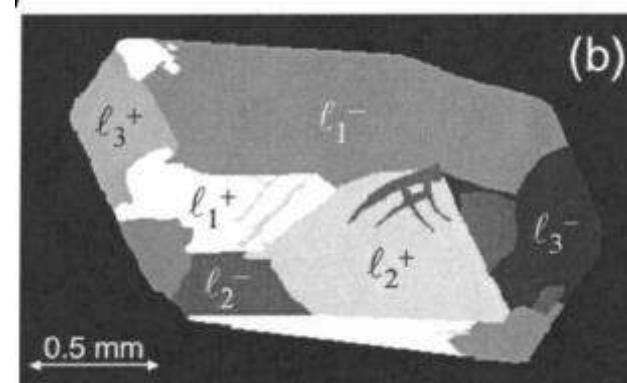
Fiebig et al. *Appl. Phys. Lett.* **66** 2906 (1995)

- Some other examples:

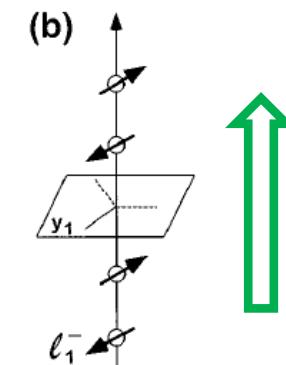
B_{SF} in $\text{FeF}_2 \approx 50$ T

B_{SF} in $\text{MnF}_2 \approx 9$ T

B_{SF} in $\text{NiO} \approx 7.5$ T



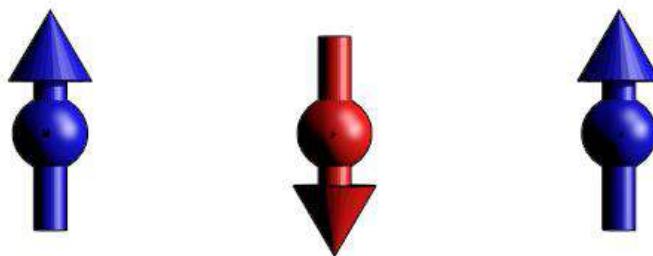
Fiebig et al. *J. Opt. Am. B* **22** 96 (2005) and *Phys. Rev. B* **54** 12681 (1996)



$B = 6.6$ T at 1.8 K
($B_{SF} \approx 5.8$ T in Cr_2O_3)

Antiferromagnetic dynamics

➤ Pioneer work by **Kittel and Keffer**



Theory of Antiferromagnetic Resonance

C. KITTEL

Bell Telephone Laboratories, Murray Hill, New Jersey
(Received April 2, 1951)

Physical Review 82 565 (1951)

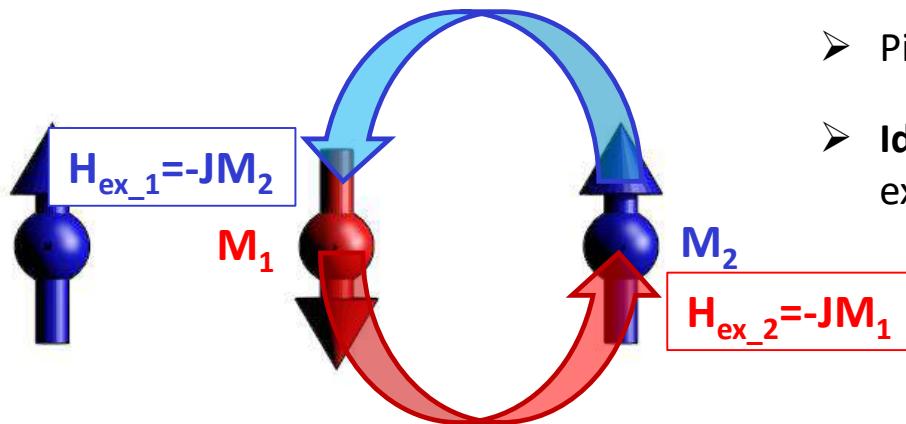
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F. KEFFER AND C. KITTEL

Department of Physics, University of California, Berkeley, California
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Physical Review 85 329 (1952)

Antiferromagnetic dynamics



- Pioneer work by **Kittel and Keffer**
- **Idea:** One sublattice precesses in the exchange field of the other

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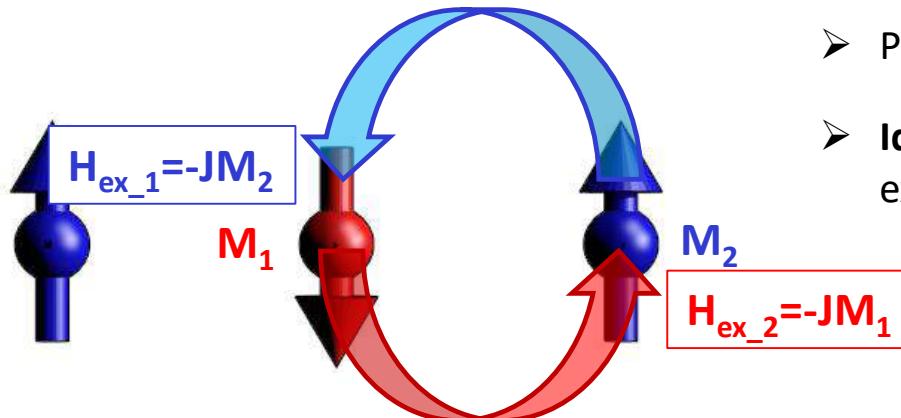
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Antiferromagnetic dynamics and ultrafast THz capabilities



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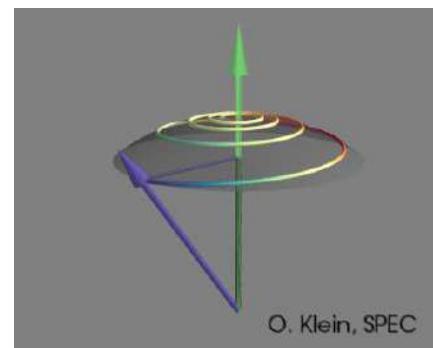
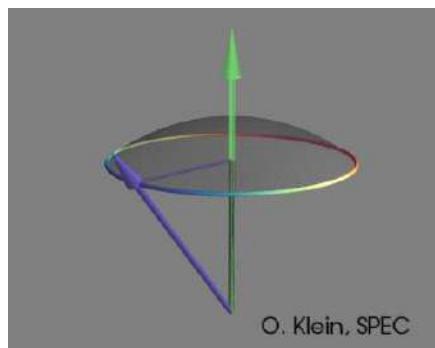
Department of Physics, University of California, Berkeley, California
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Physical Review 85 329 (1952)

Reminder: magnetization (spin) dynamics & ferromagnetic resonance

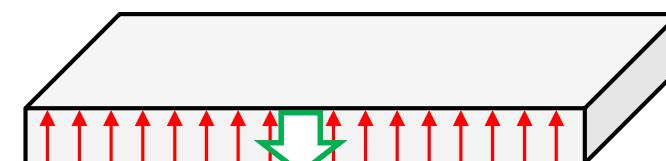
- Governed by the Landau-Lifshitz-Gilbert equation

$$\frac{d\mathbf{m}}{dt} = \underbrace{-\mu_0 \gamma \mathbf{m} \times \mathbf{H}_{eff}}_{\text{precession}} + \underbrace{\alpha \mathbf{m} \times \frac{d\mathbf{m}}{dt}}_{\text{damping}}$$



\mathbf{H}_{eff} : effective magnetic field / depends on the various magnetic energies (dipolar, anisotropy, exchange etc...)

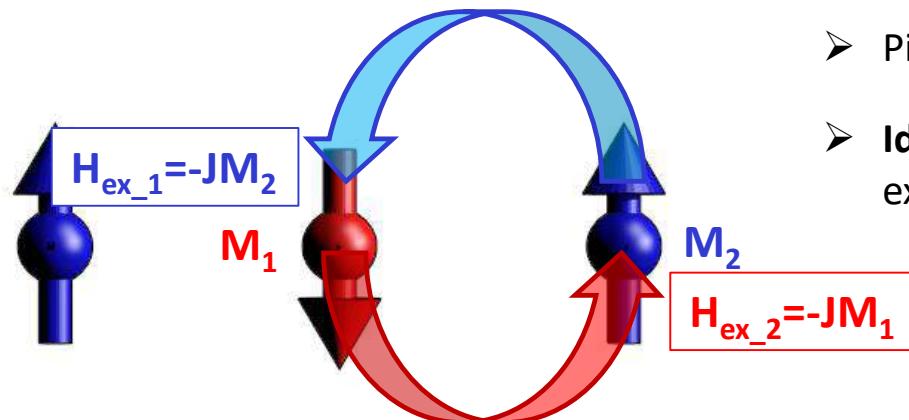
γ : gyromagnetic ratio (≈ 28 GHz/T for electron spin)



Ferromagnetic resonance typically in the GHz range

$\mathbf{H}_{eff} \approx \mathbf{H}_{dipolar} \approx \mathbf{M}_s \approx 1$ Tesla

Antiferromagnetic dynamics



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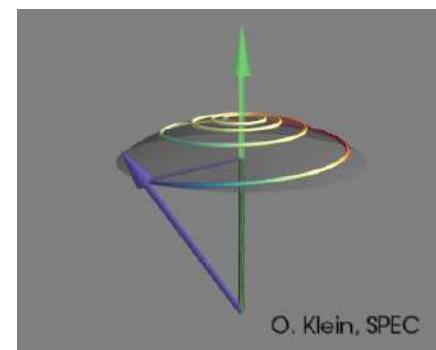
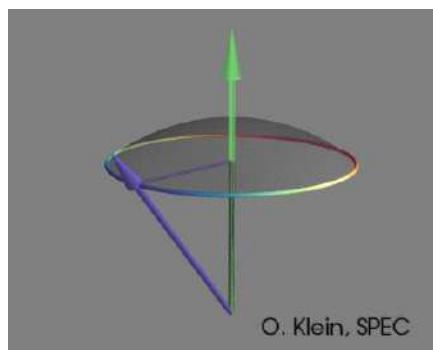
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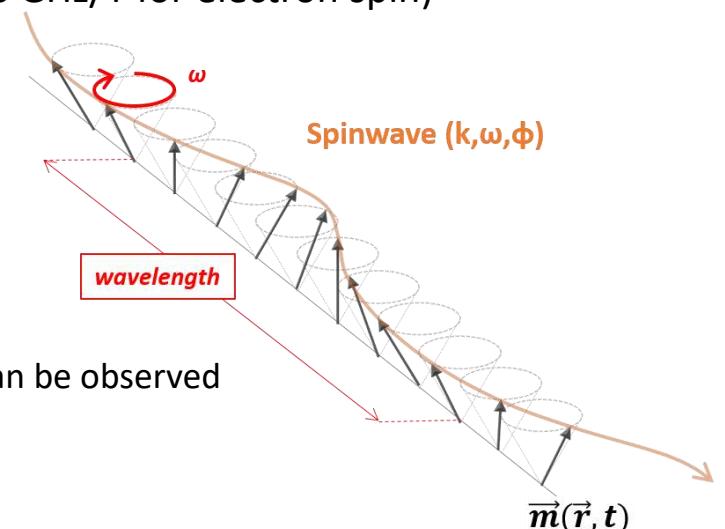
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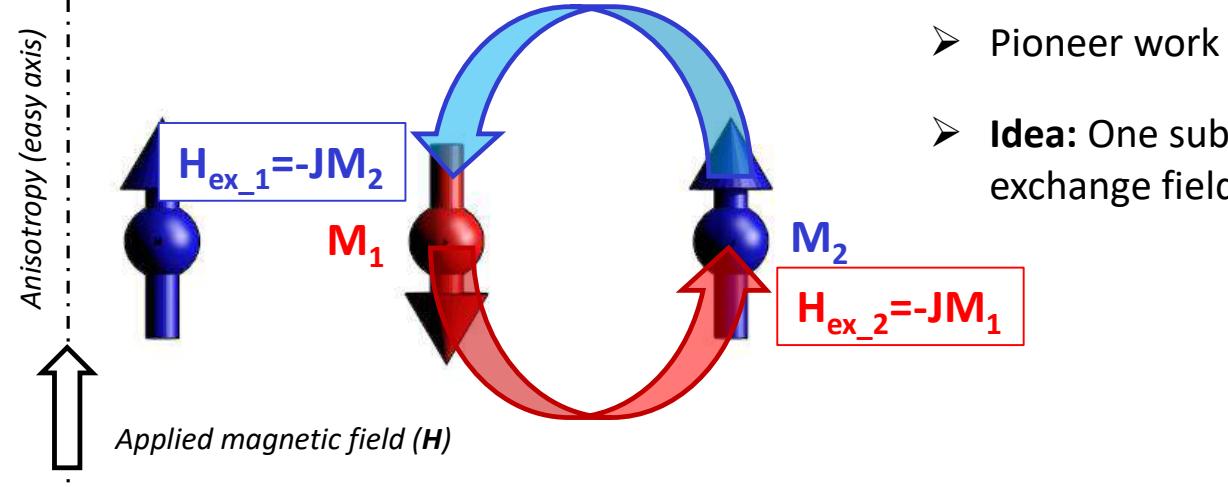
Case of high k-vector spinwaves:

Exchange field plays a role

➡ higher frequencies can be observed



Antiferromagnetic dynamics



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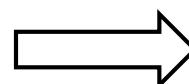
Physical Review 85 329 (1952)

Antiferromagnetic resonance: two coupled equations

$$\frac{d\mathbf{m}_1}{dt} = -\mu_0 \gamma \mathbf{m}_1 \times (-J\mathbf{m}_2 + \mathbf{H}_A - \mathbf{H})$$

$$\frac{d\mathbf{m}_2}{dt} = -\mu_0 \gamma \mathbf{m}_2 \times (-J\mathbf{m}_1 + \mathbf{H}_A + \mathbf{H})$$

Antiferromagnetic resonance frequency:

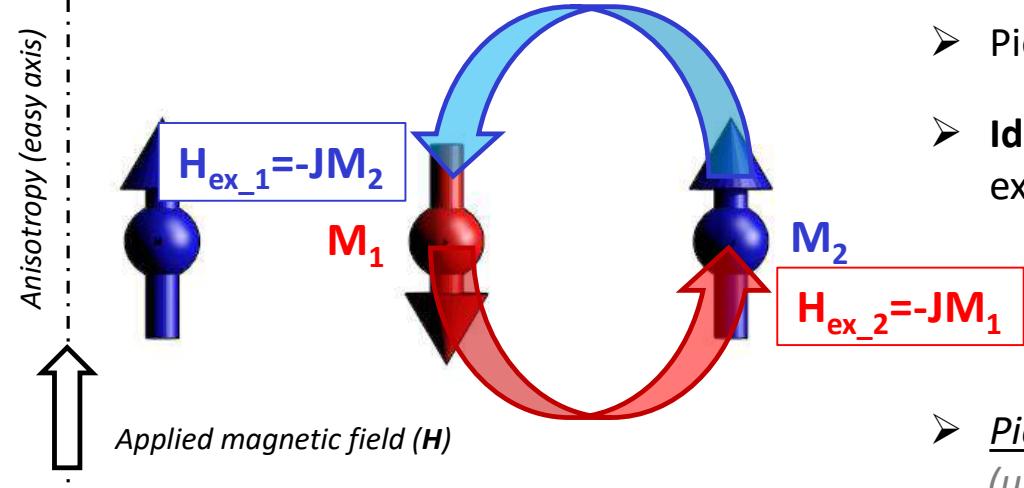


$$\omega_{res} = \mu_0 \gamma \left(\sqrt{\mathbf{H}_A(\mathbf{H}_A + 2\mathbf{H}_{ex})} \pm \mathbf{H} \right)$$

Usually $\mathbf{H}_{ex} \gg \mathbf{H}_A \implies \omega_{res} \approx \mu_0 \gamma \left(\sqrt{2\mathbf{H}_{ex}\mathbf{H}_A} \pm \mathbf{H} \right)$

- \mathbf{H}_{ex} from some tens to several hundreds of Tesla
- High resonance frequencies at k=0: **sub-THz and THz ranges**
- Not so easy to assess

Antiferromagnetic dynamics



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Department of Physics, University of California, Berkeley, California
(Received October 1, 1951)

Physical Review 85 329 (1952)

- Pioneer experimental studies:
(using some tricks to decrease the AF resonance into the GHz range)

1/ Low T_N antiferromagnet \longrightarrow Small H_{ex}

Antiferromagnetism and Antiferromagnetic Resonance in $\text{CuBr}_2 \cdot 2\text{H}_2\text{O}$ at 9800 Mc/sec

Antiferromagnetic resonance frequency:

$$\omega_{\text{res}} \approx \mu_0 \gamma \left(\sqrt{2H_{\text{ex}}H_A} \pm H \right)$$

M. DATE
Research Institute for Iron, Steel, and Other Metals, Tôhoku University, Sendai, Japan

(Received June 18, 1956)

Physical Review 104 623 (1956)

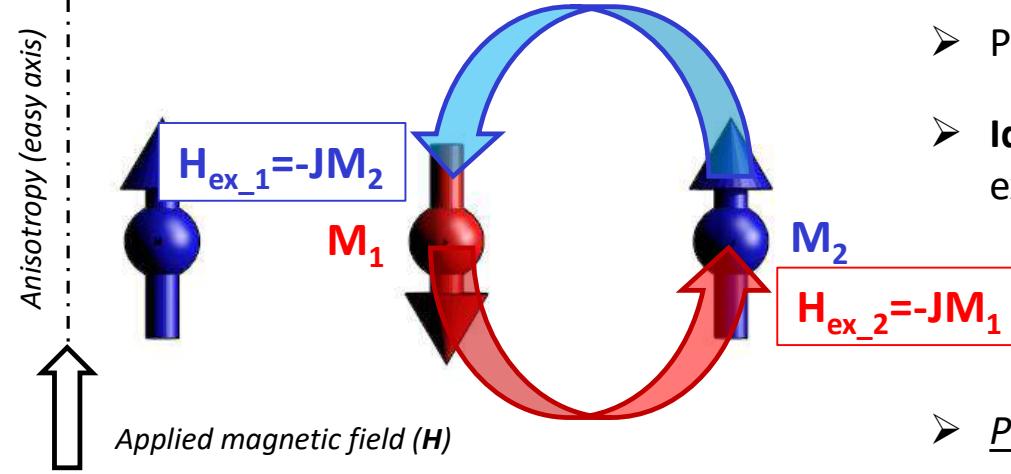
2/ Heating up to T_N \longrightarrow reducing H_A

Antiferromagnetic Resonance in Cr_2O_3

EDWARD S. DAYHOFF
United States Naval Ordnance Laboratory, White Oak, Silver Spring, Maryland
(Received February 28, 1957)

Physical Review 107 84 (1957)

Antiferromagnetic dynamics



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Department of Physics, University of California, Berkeley, California
(Received October 1, 1951)

Physical Review 85 329 (1952)

- Pioneer experimental studies in sub-THz and THz ranges:

Antiferromagnetic Resonance in MnF_2 †

FRED M. JOHNSON* AND ARTHUR H. NETHERCOT, JR.‡
Columbia Radiation Laboratory, Columbia University, New York, New York
(Received November 25, 1958)

Physical Review 114 709 (1959)

$f_{\text{res}} = 260 \text{ GHz}$

Antiferromagnetic resonance frequency:

$$\omega_{\text{res}} \approx \mu_0 \gamma \left(\sqrt{2H_{\text{ex}}H_A} \pm H \right)$$

Antiferromagnetic Resonance in FeF_2 at Far-Infrared Frequencies*†

R. C. OHLMANN‡ AND M. TINKHAM
Department of Physics, University of California, Berkeley, California
(Received March 13, 1961)

Physical Review 123 425 (1961)

$f_{\text{res}} = 1.5 \text{ THz}$

Far Infrared Antiferromagnetic Resonance in MnO and NiO †

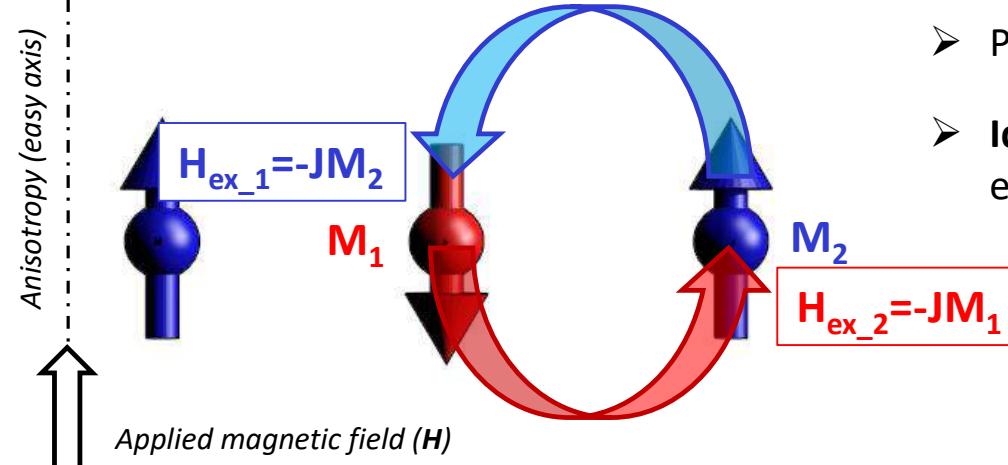
A. J. SIEVERS, III,* AND M. TINKHAM
Department of Physics, University of California, Berkeley, California
(Received 27 September 1962)

Physical Review 129 1566 (1962)

$f_{\text{res NiO}} = 1.1 \text{ THz}$

$f_{\text{res MnO}} = 0.82 \text{ THz}$

Antiferromagnetic dynamics



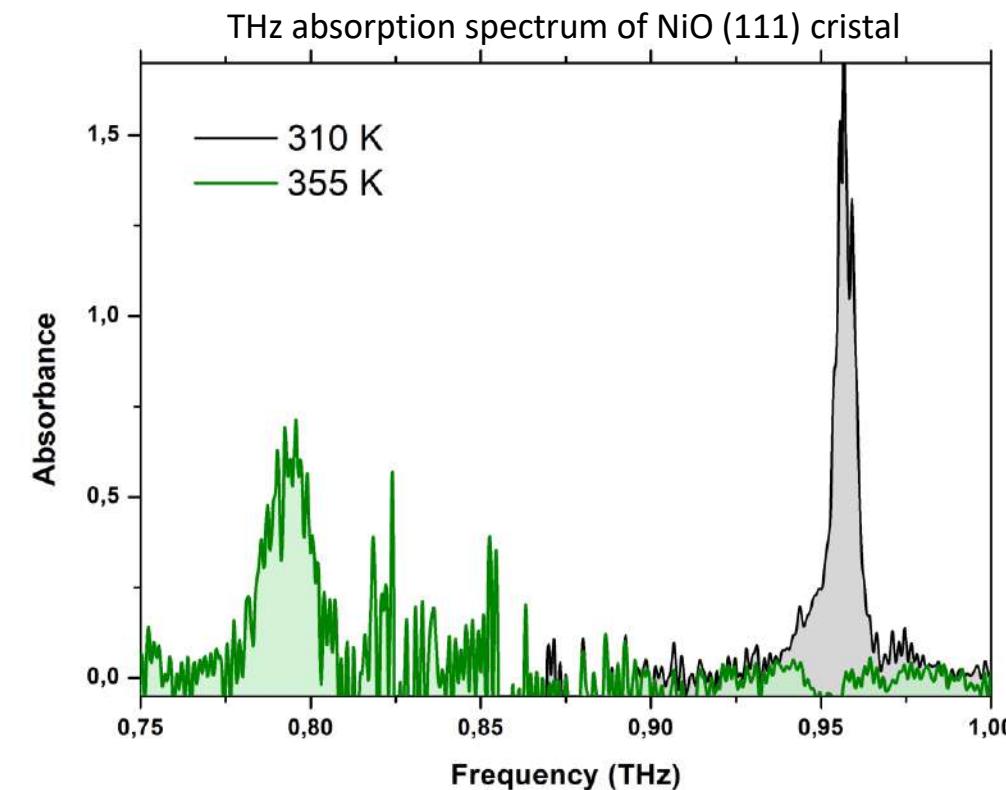
- Pioneer work by **Kittel and Keffer**
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Physical Review 85 329 (1952)



Antiferromagnetic resonance frequency:

$$\omega_{res} \approx \mu_0 \gamma \left(\sqrt{2H_{ex}H_A} \pm H \right)$$

Antiferromagnetic dynamics

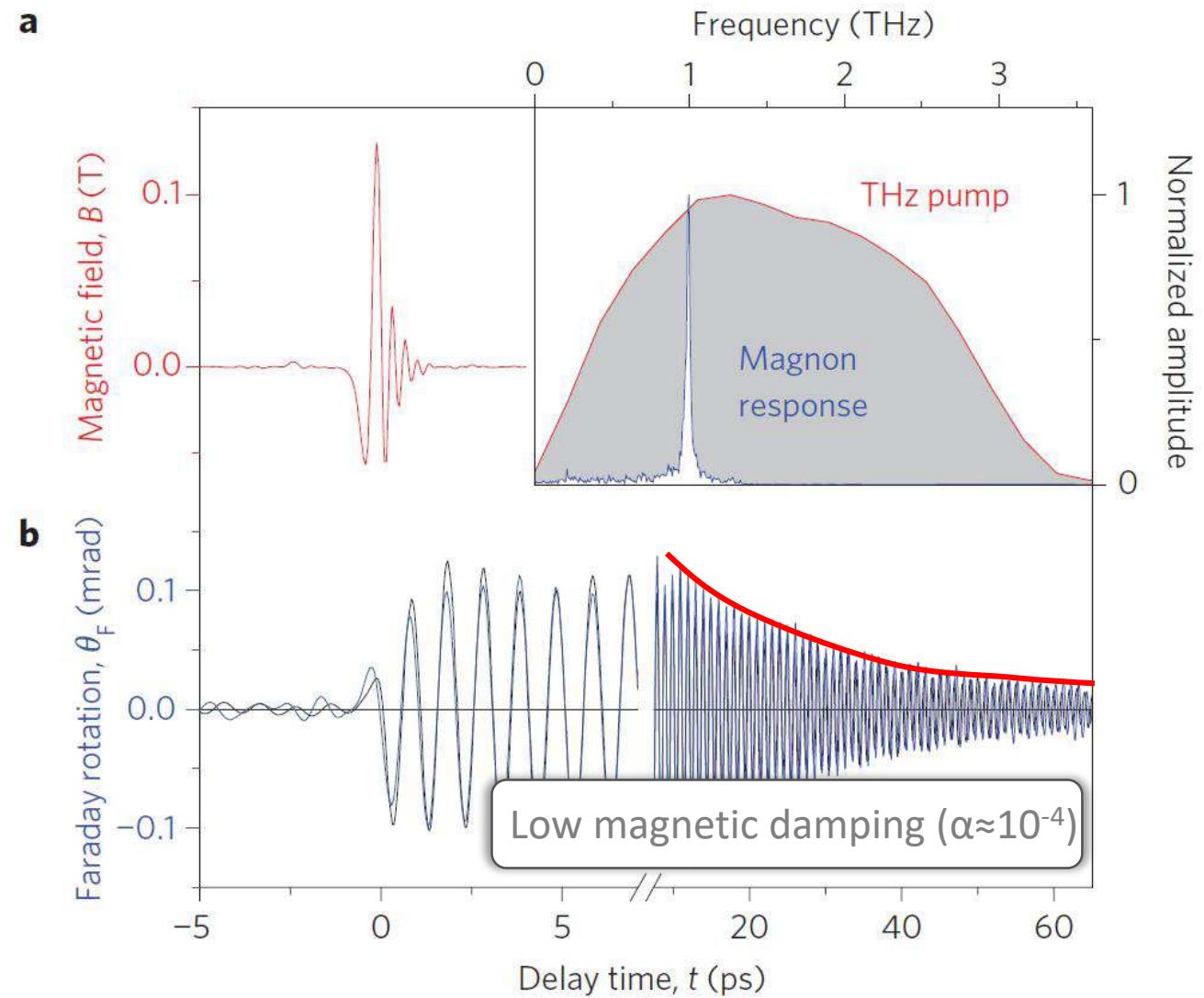
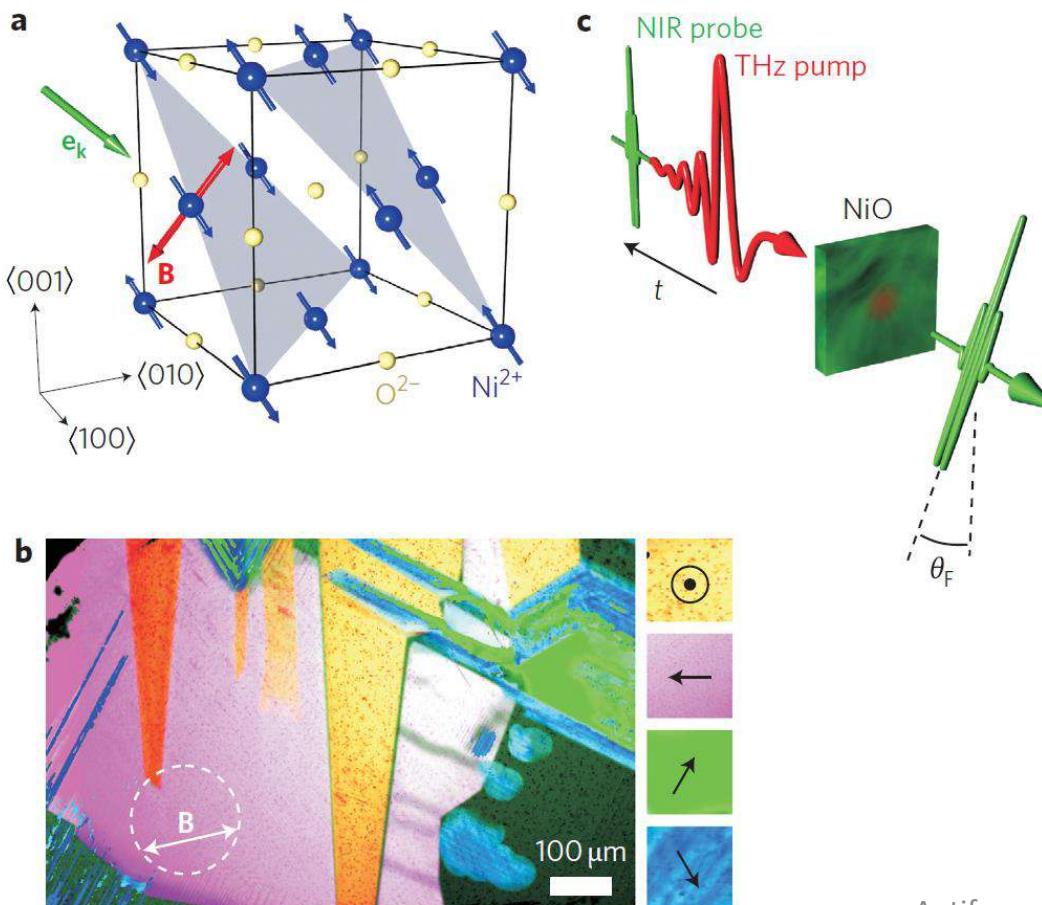
nature
photronics

LETTERS

PUBLISHED ONLINE: 21 NOVEMBER 2010 | DOI: 10.1038/NPHOTON.2010.259

Coherent terahertz control of antiferromagnetic spin waves

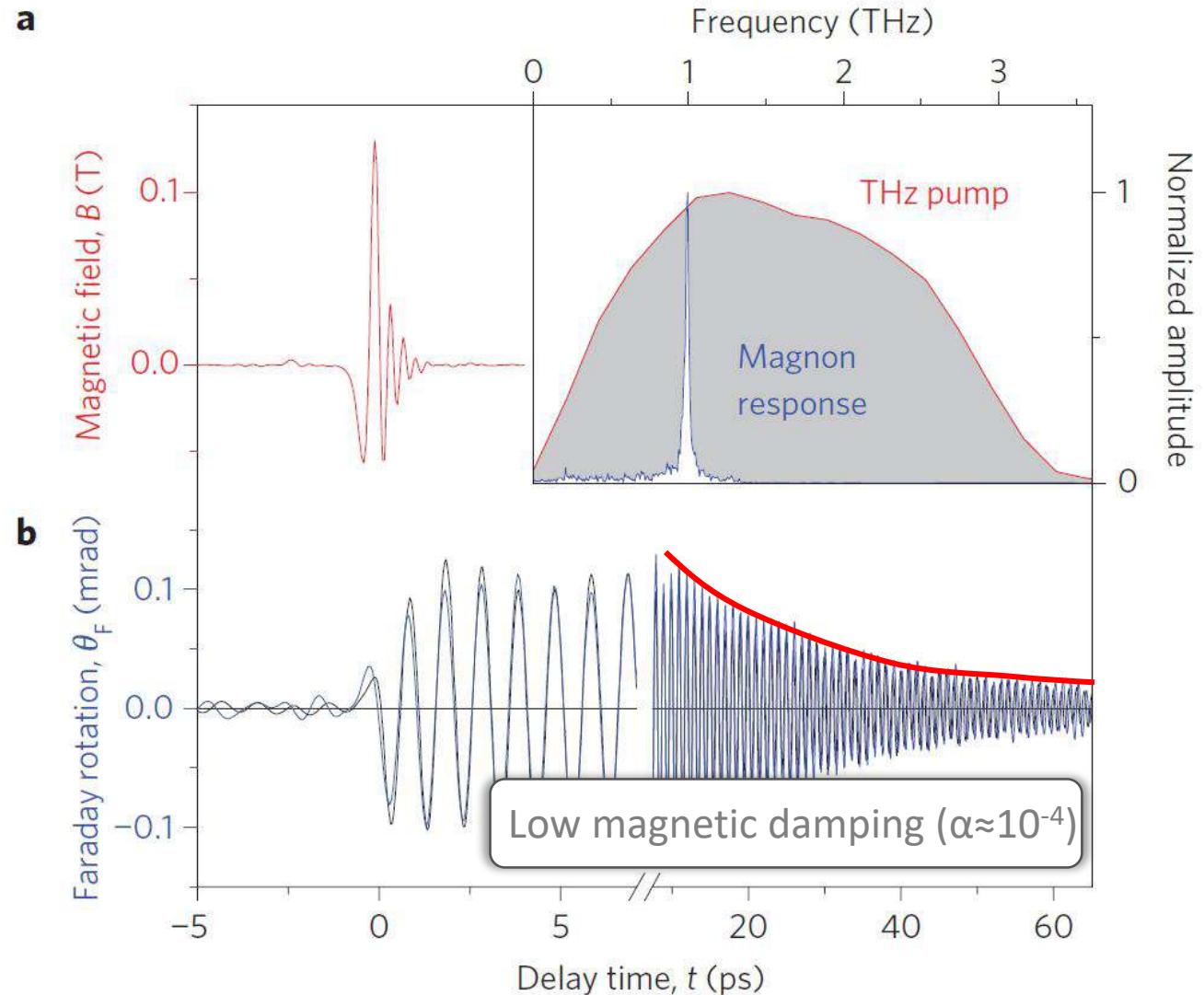
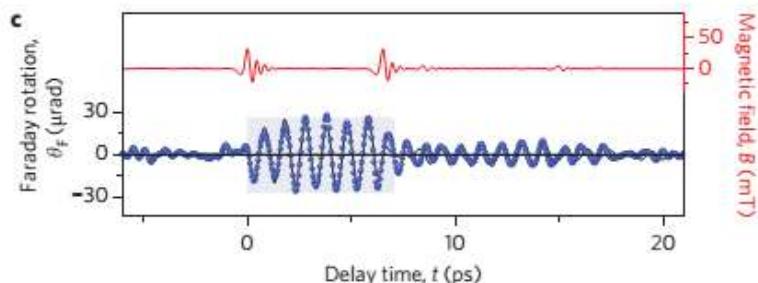
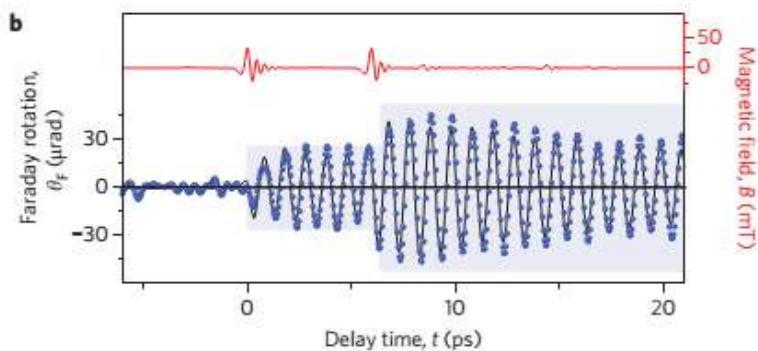
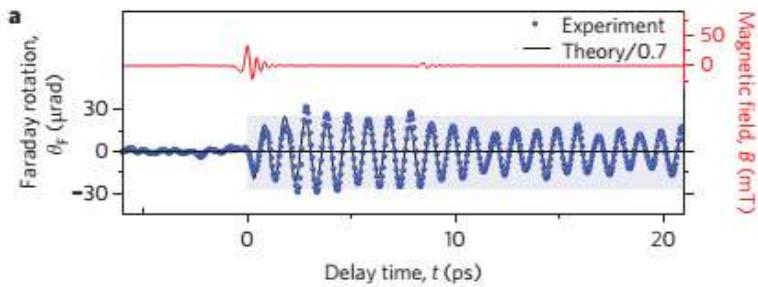
Tobias Kampfrath^{1,2,3†*}, Alexander Sell^{1‡}, Gregor Klatt¹, Alexej Pashkin¹, Sebastian Mährlein¹, Thomas Dekorsy¹, Martin Wolf², Manfred Fiebig⁴, Alfred Leitenstorfer¹ and Rupert Huber^{1†*}



Antiferromagnetic dynamics

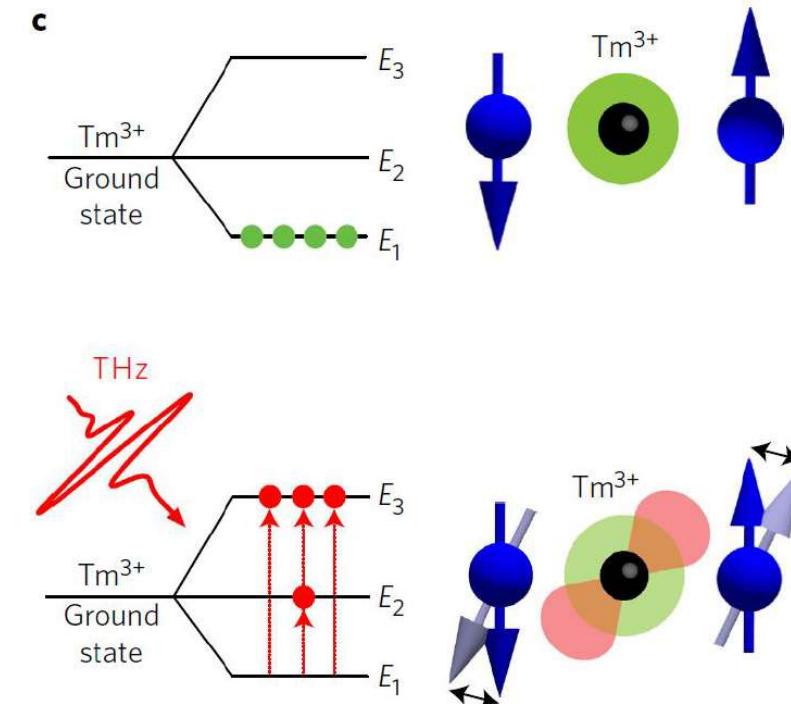
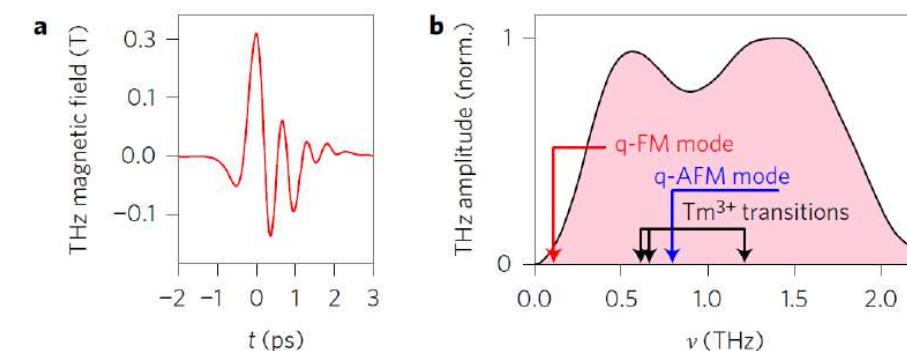
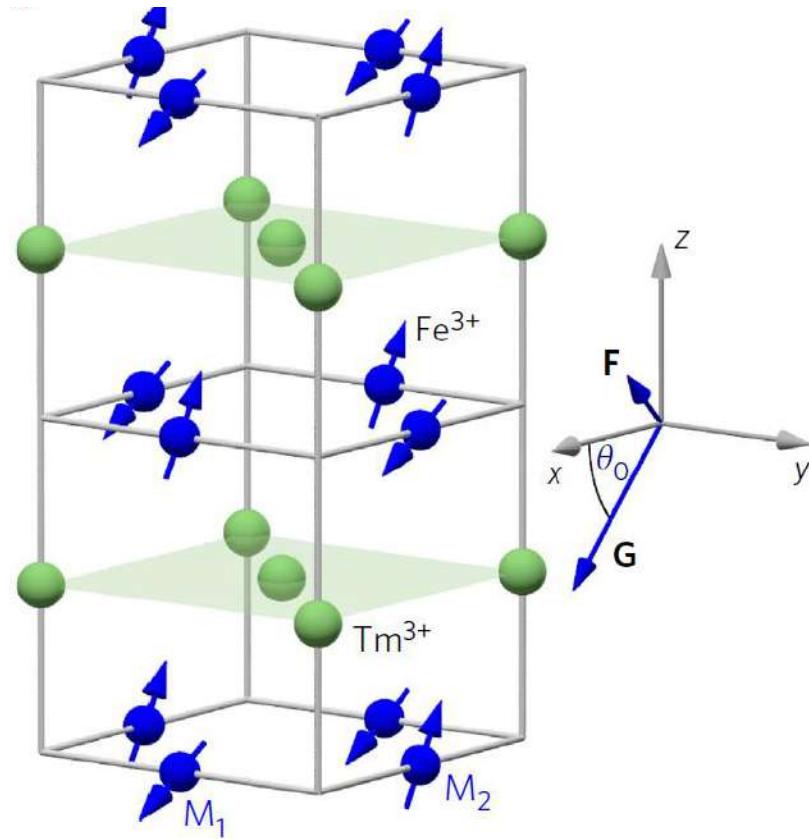
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Tobias Kampfrath^{1,2,3†*}, Alexander Sell^{1‡}, Gregor Klatt¹, Alexej Pashkin¹, Sebastian Mährlein¹, Thomas Dekorsy¹, Martin Wolf², Manfred Fiebig⁴, Alfred Leitenstorfer¹ and Rupert Huber^{1†*}



Nonlinear spin control by terahertz-driven anisotropy fields

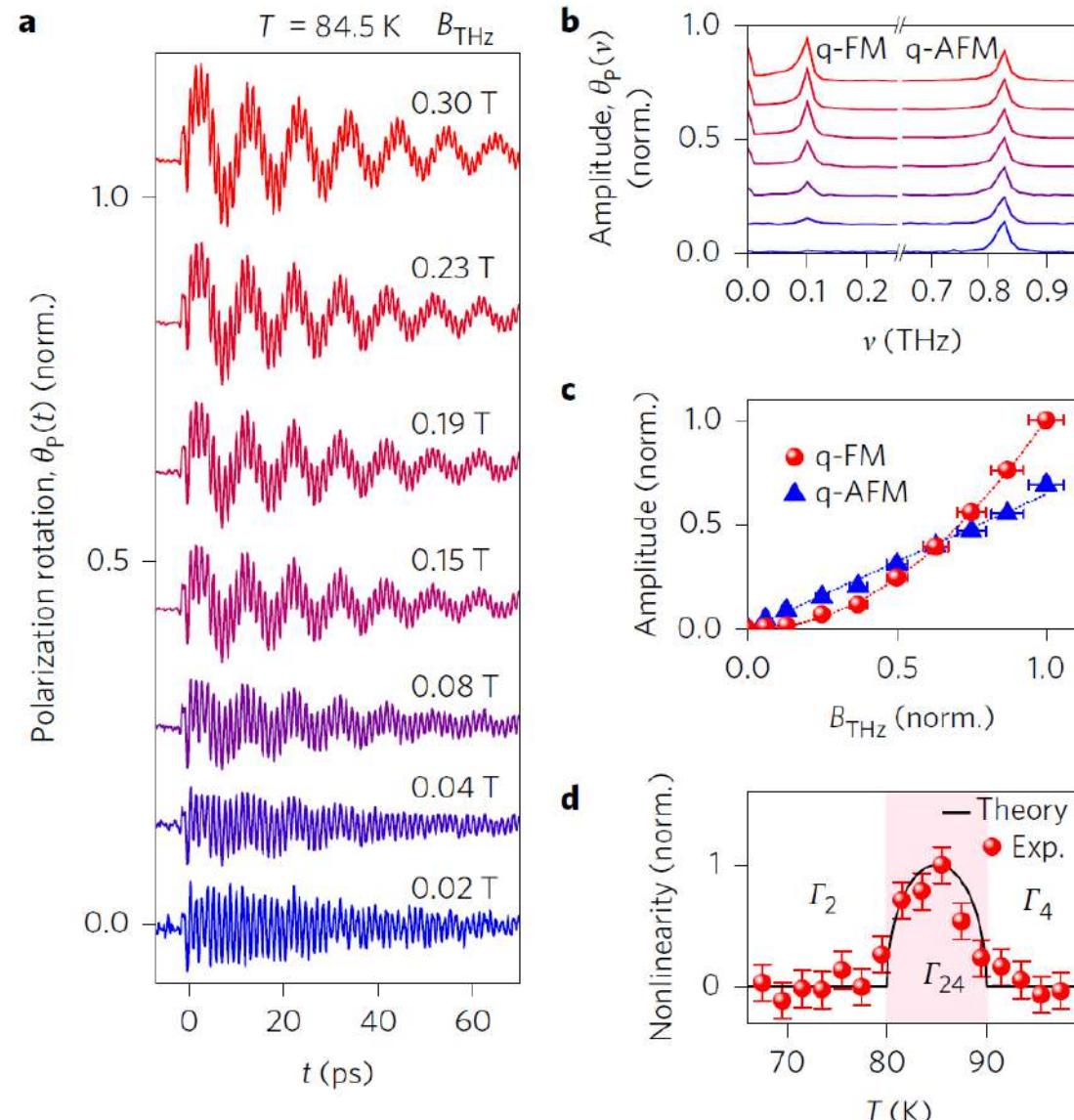
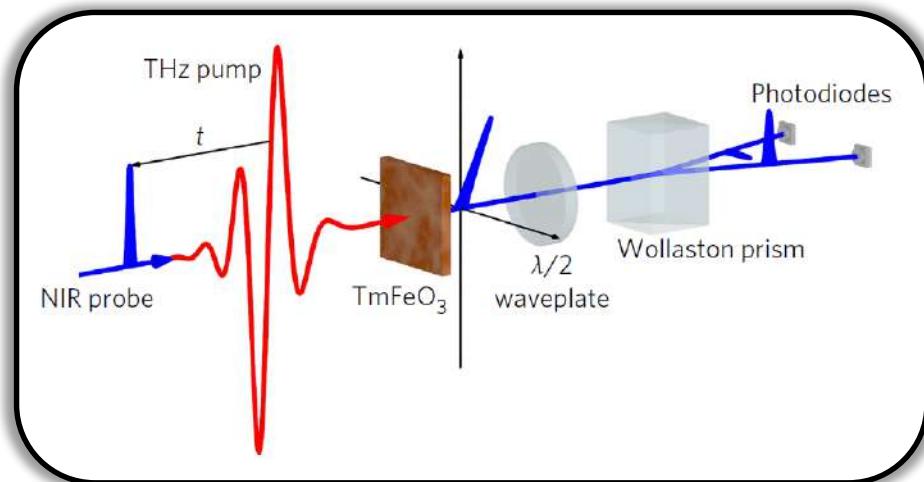
S. Baierl¹, M. Hohenleutner¹, T. Kampfrath², A. K. Zvezdin^{3,4,5}, A. V. Kimel^{4,6}, R. Huber^{1*}
and R. V. Mikhaylovskiy^{6*}



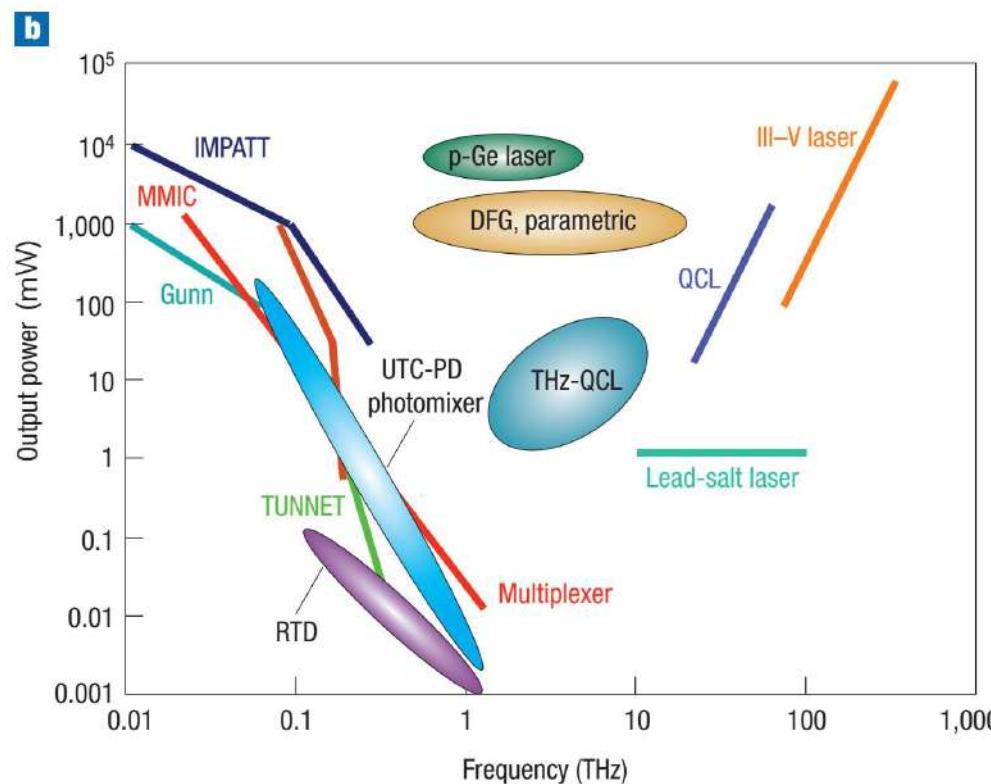
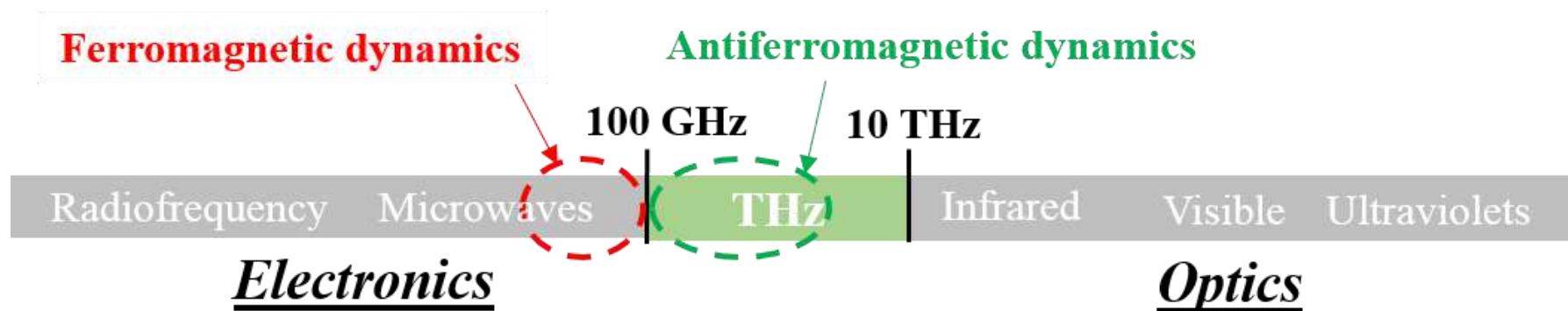
Antiferromagnetic dynamics and ultrafast THz capabilities

Nonlinear spin control by terahertz-driven anisotropy fields

S. Baierl¹, M. Hohenleutner¹, T. Kampfrath², A. K. Zvezdin^{3,4,5}, A. V. Kimel^{4,6}, R. Huber^{1*}
and R. V. Mikhaylovskiy^{6*}



Antiferromagnetic dynamics

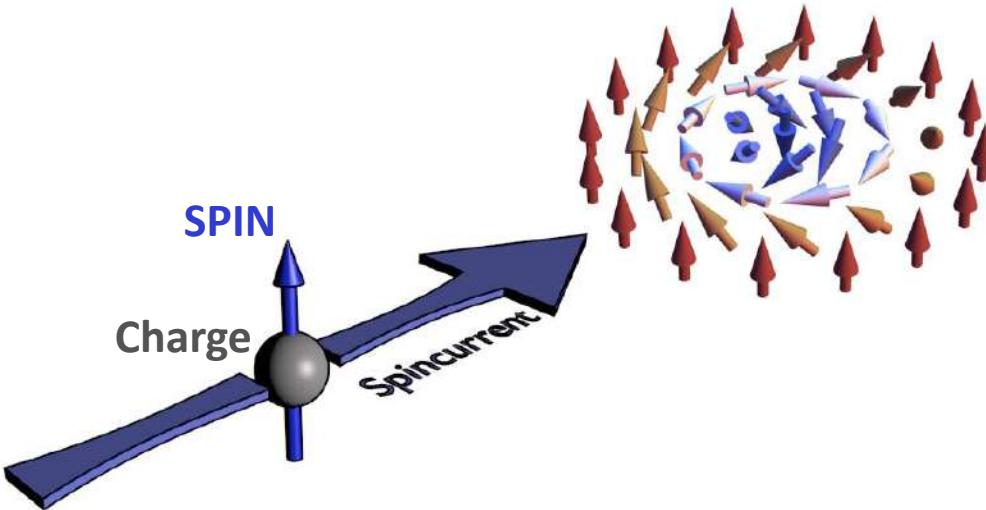


- Antiferromagnetic dynamics : in the THz range
 - AF could play a role in future ultrafast devices
- However:**
- Their efficient actuation remains a challenge

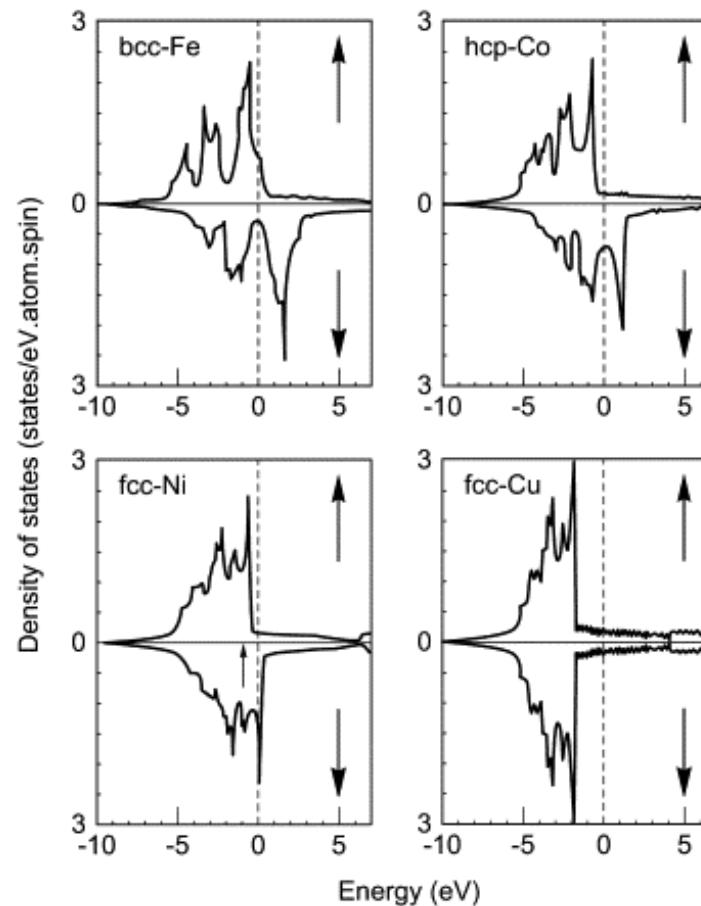
➡ Role of spin currents?

Spin currents and Antiferromagnets

Spintronics: Interplay between **spincurrents** and **magnetic textures**



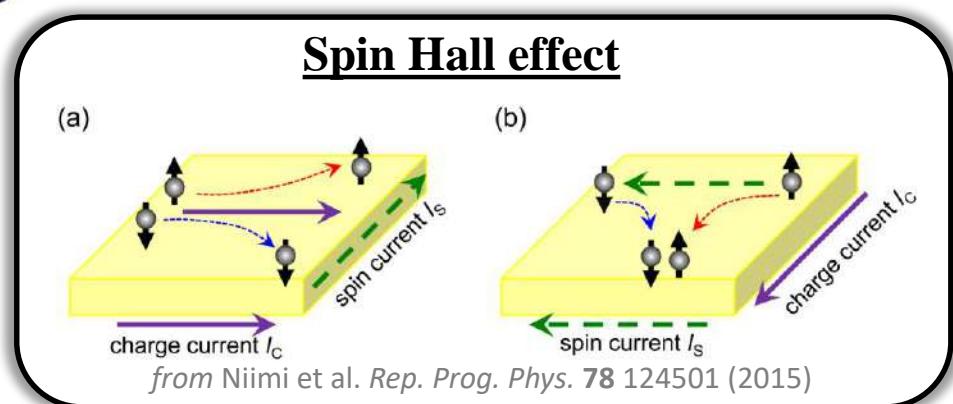
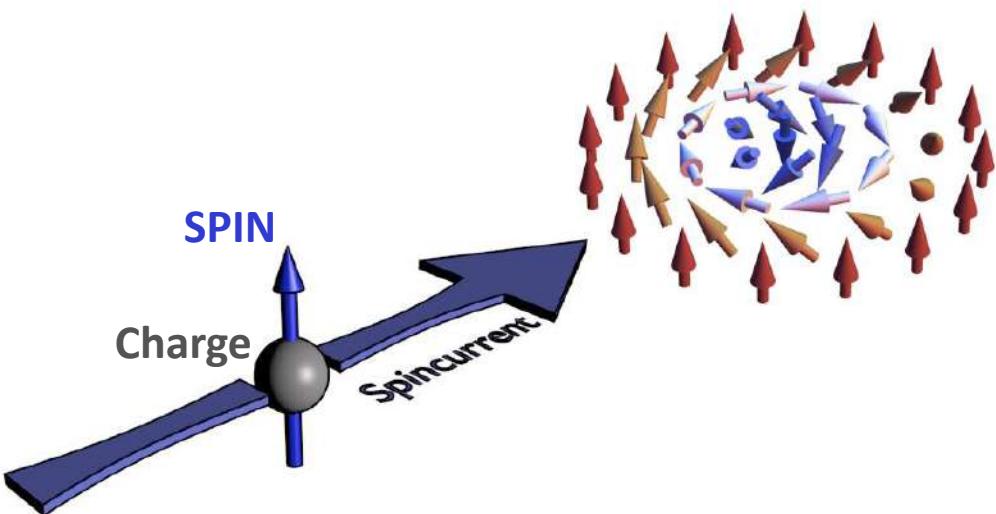
➤ 1/ Spin-polarized electrical currents (... *in ferromagnetic metals*)



Unbalanced spin density of state at the fermi energy

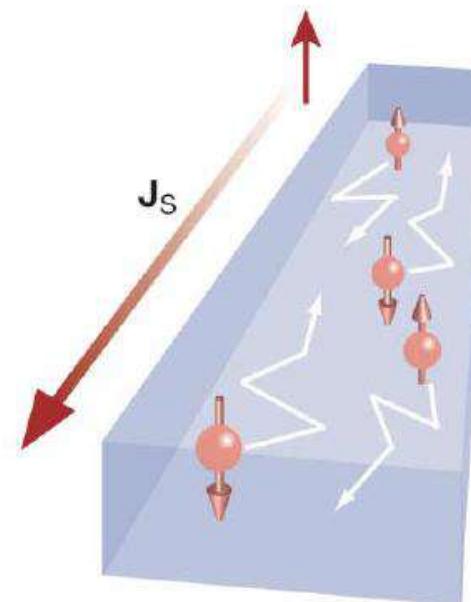
Spin currents and Antiferromagnets

Spintronics: Interplay between **spincurrents** and **magnetic textures**

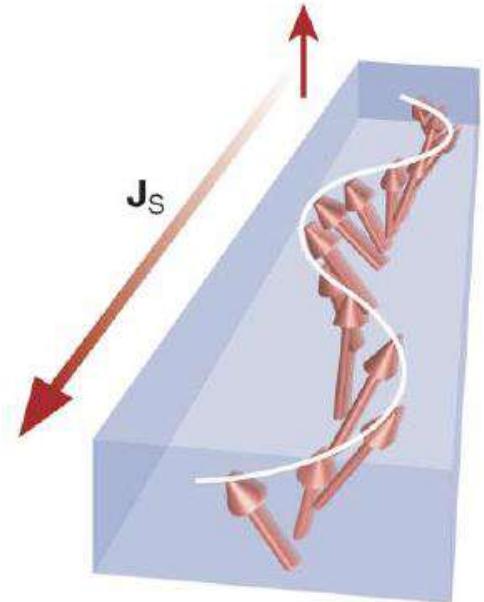


➤ 2/ Pure spincurrents

a Conduction-electron spin current



b Spin-wave spin current

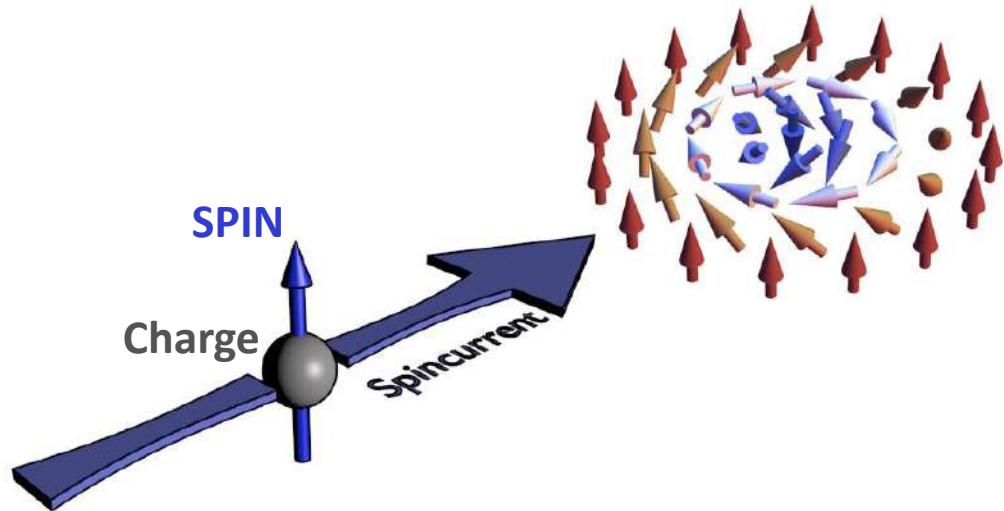


Kajiwara et al. *Nature* **464** 262 (2010)

Also at Rashba-splitted interfaces: **Rashba-Edelstein effect**

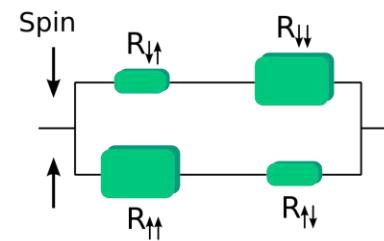
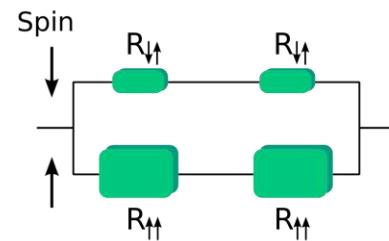
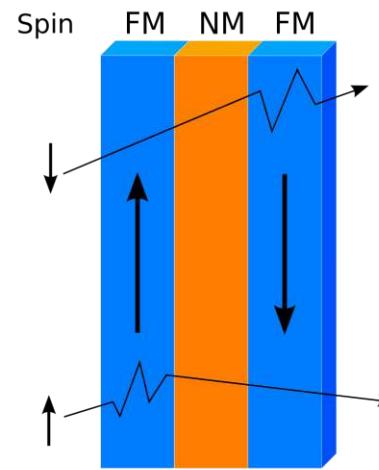
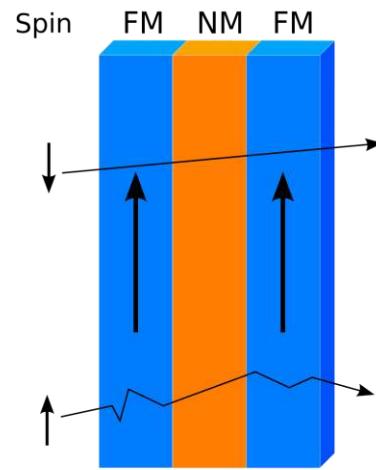
Spin currents and Antiferromagnets

Spintronics: Interplay between *spin currents* and *magnetic textures*



Spin currents and Antiferromagnets

Spintronics: Interplay between *spin currents* and *magnetic textures*



- The “origins” of spintronics: Giant Magneto-Resistance (GMR)

Baibich et al. *Phys. Rev. Lett.* **61** 2472 (1988)

Binasch et al. *Phys. Rev. B* **39** 4828 (1989)

- Its reciprocal effect: Spin-Transfer Torque's (STT)

Ralph et al. *J. Magn. Magn. Mater.* **320**, 1190 (2008) (review article)

1997: 1st introduction of GMR in HDD



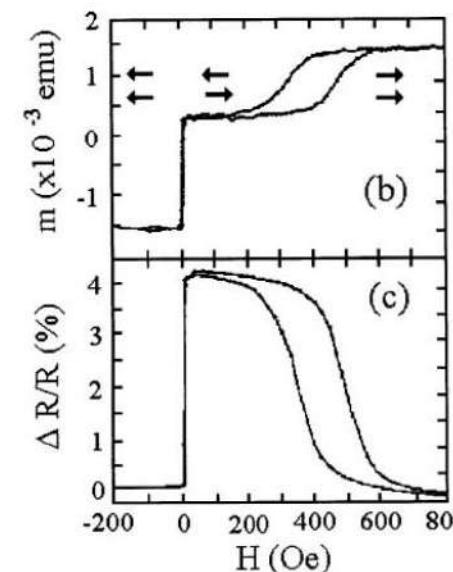
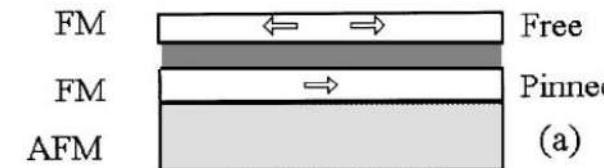
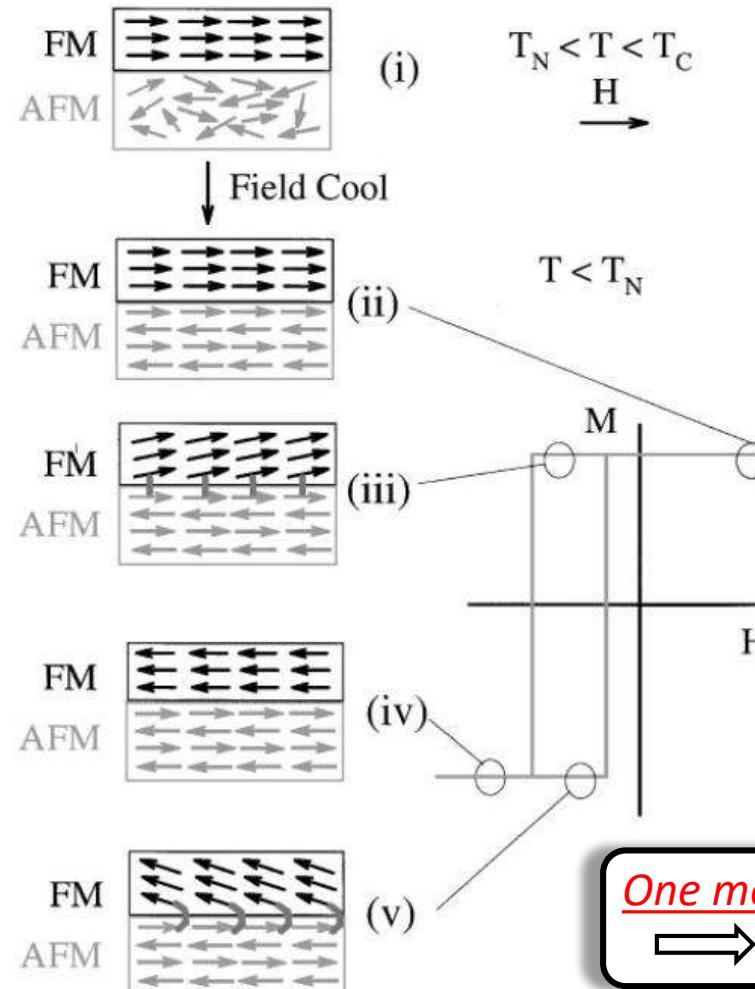
Image from <https://doi.org/10.1073/pnas.1302494110>

Antiferromagnets have already been integrated in spintronics devices for decades only as ... **passive elements...**

Spin currents and Antiferromagnets

Antiferromagnets have already integrated in spintronics devices for decades only as ... **passive elements...**

➤ Exchange coupling & exchange bias:



One motivation behind AF spintronics:

➡ AF as active element in spintronic devices : use of their interesting properties

Spin currents and Antiferromagnets : Transport

➤ AF as active element in spintronic devices :

nature
materials

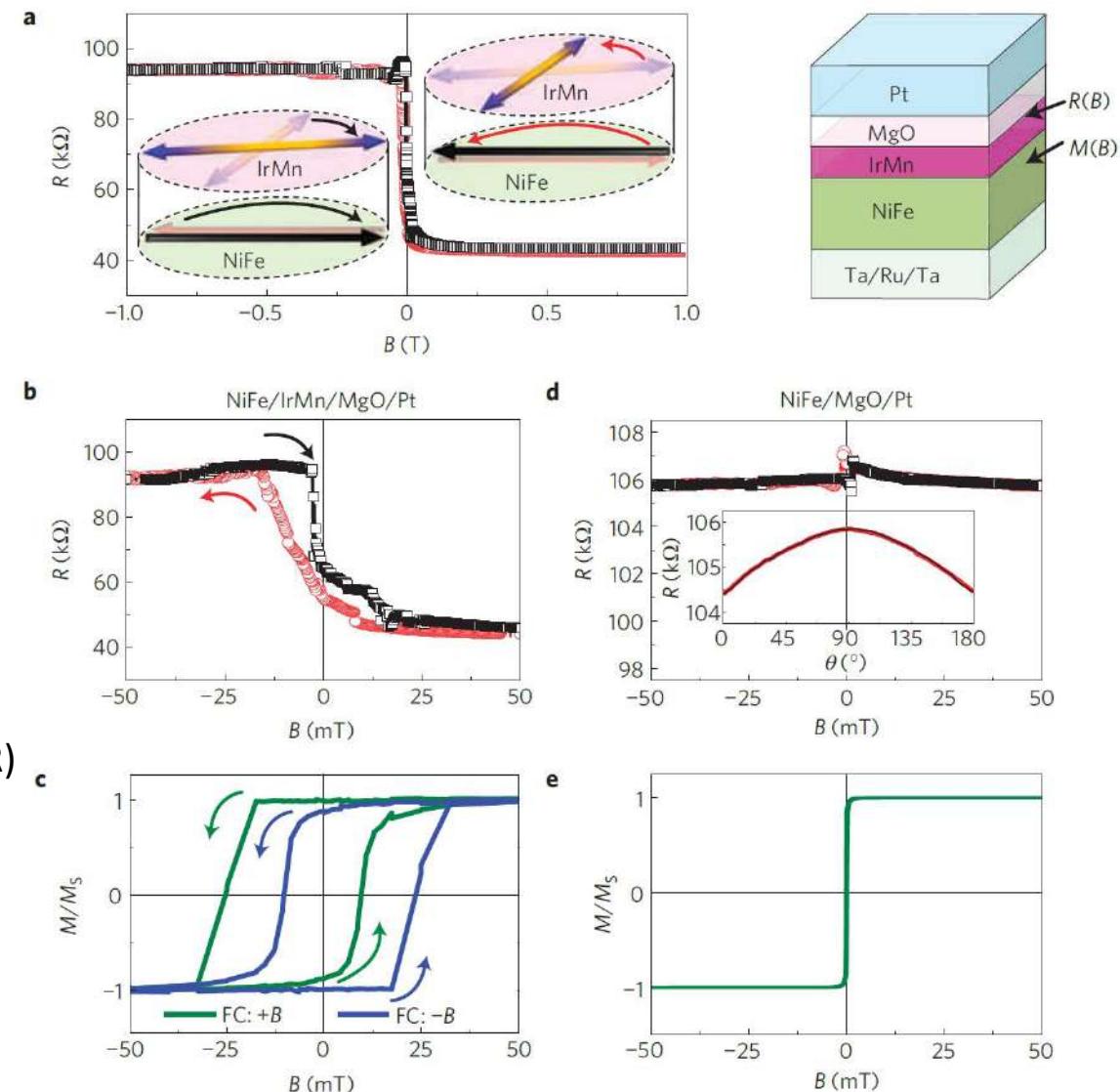
LETTERS

PUBLISHED ONLINE: 13 MARCH 2011 | DOI:10.1038/NMAT2983

A spin-valve-like magnetoresistance of an antiferromagnet-based tunnel junction

B. G. Park^{1*}, J. Wunderlich^{1,2}, X. Martí³, V. Holý³, Y. Kuroski⁴, M. Yamada⁴, H. Yamamoto⁴, A. Nishide⁴, J. Hayakawa⁴, H. Takahashi^{1,4}, A. B. Shick⁵ and T. Jungwirth^{2,6*}

- Antiferromagnetic tunneling anisotropic magnetoresistance (AFM-TAMR)
- Large spin-valve like signal
- First demonstrations with metallic AF.



Spin currents and Antiferromagnets : Transport



A LETTERS JOURNAL EXPLORING
THE FRONTIERS OF PHYSICS

➤ What about insulating AF oxides? :

December 2014

EPL, 108 (2014) 57005
doi: 10.1209/0295-5075/108/57005

www.epljournal.org

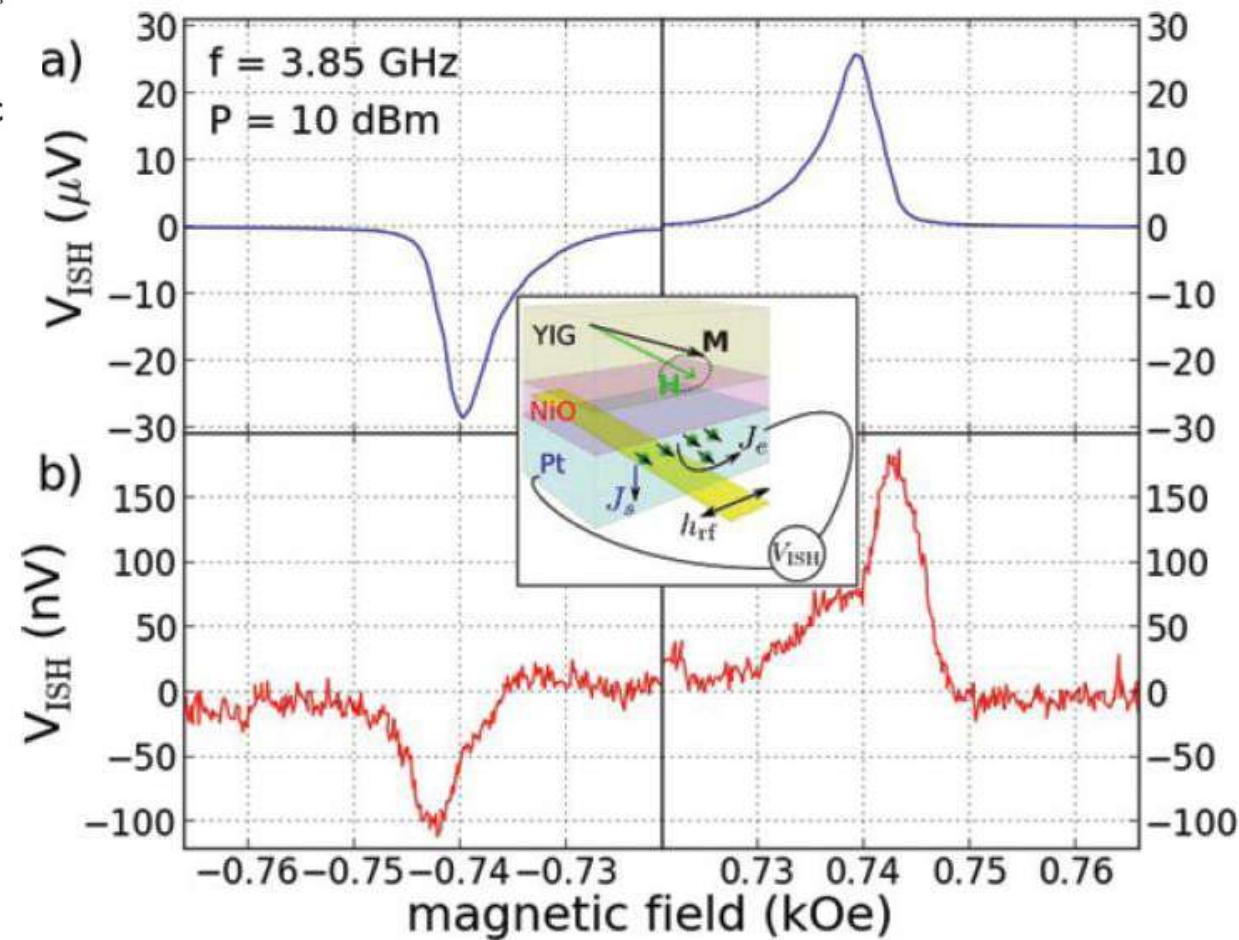
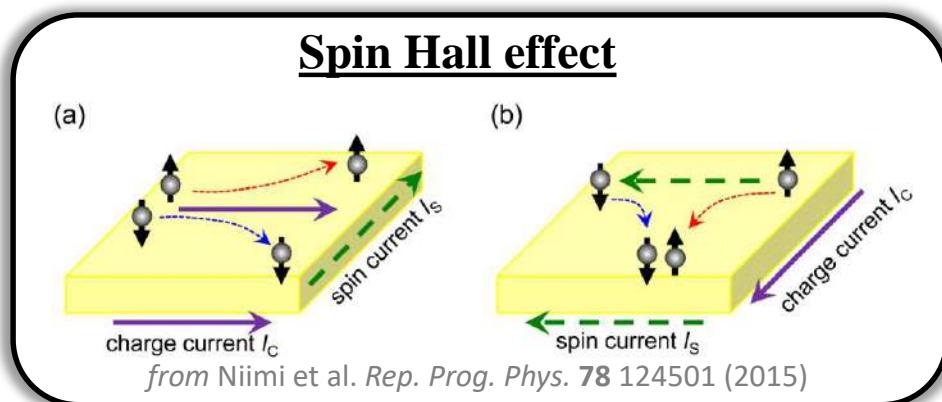
Conduction of spin currents through insulating antiferromagnetic oxides

CHRISTIAN HAHN¹, GRÉGOIRE DE LOUBENS¹, VLADIMIR V. NALETOV^{1,2}, JAMAL BEN YOUSSEF³, OLIVIER KLEIN¹ and MICHEL VIRET^{1(a)}

¹ Service de Physique de l'État Condensé (CNRS URA 2464), CEA Saclay - 91191 Gif-sur-Yvette, France

² Institute of Physics, Kazan Federal University - Kazan 420008, Russian Federation

³ Université de Bretagne Occidentale, Laboratoire de Magnétisme de Bretagne CNRS - 6 Avenue Le Gorgeu, 29285 Brest, France



Spin currents and Antiferromagnets : Transport



A LETTERS JOURNAL EXPLORING
THE FRONTIERS OF PHYSICS

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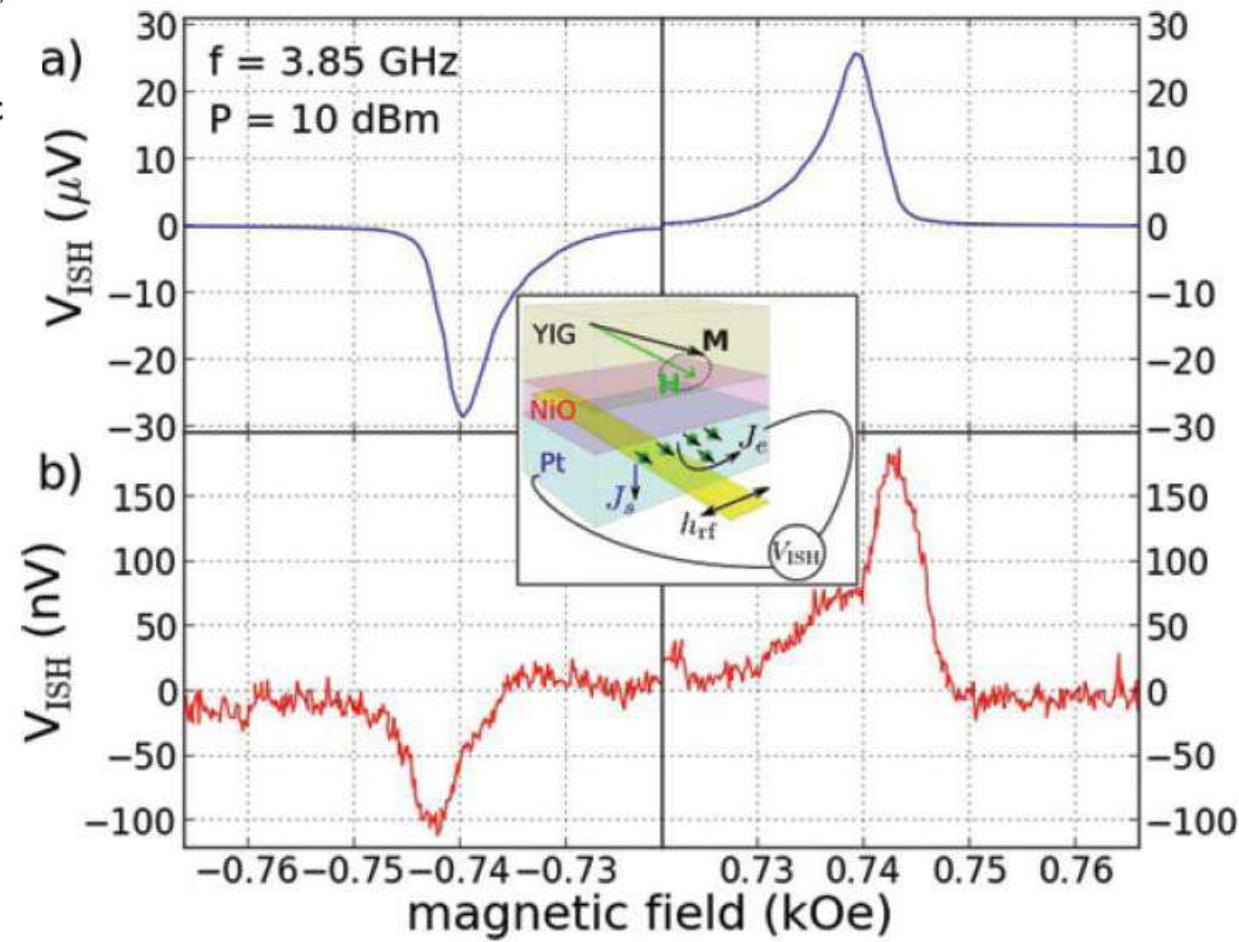
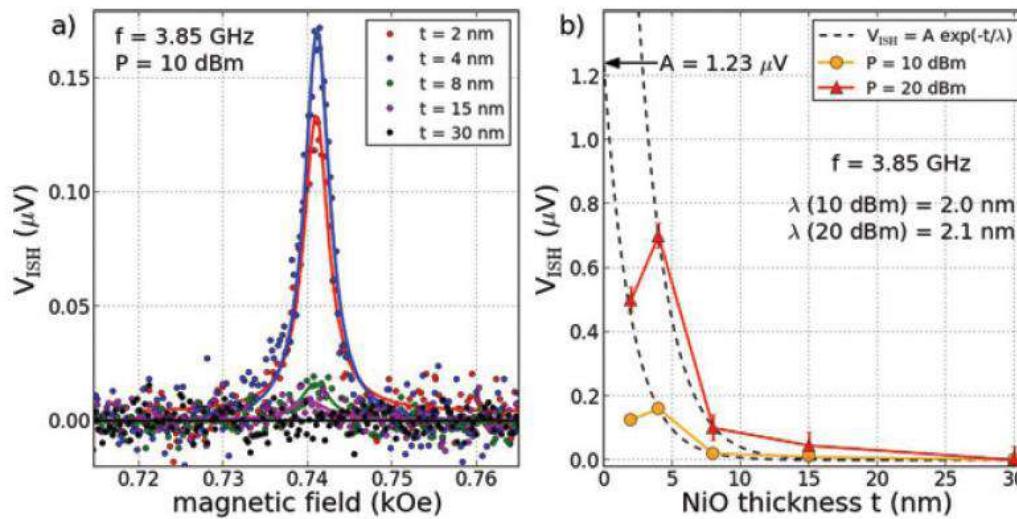
Conduction of spin currents through insulating antiferromagnetic oxides

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Spin currents and Antiferromagnets : Transport



A LETTERS JOURNAL EXPLORING
THE FRONTIERS OF PHYSICS

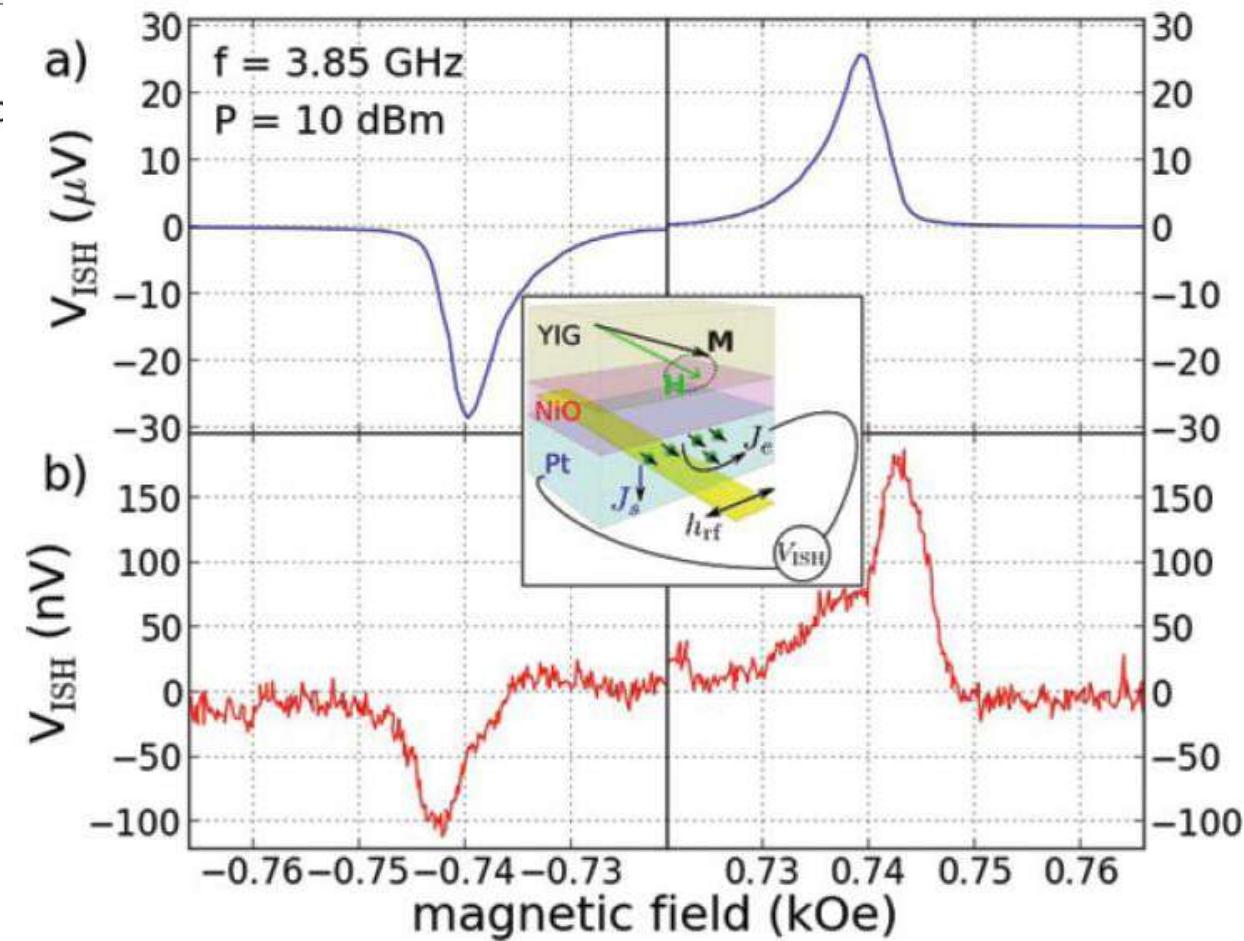
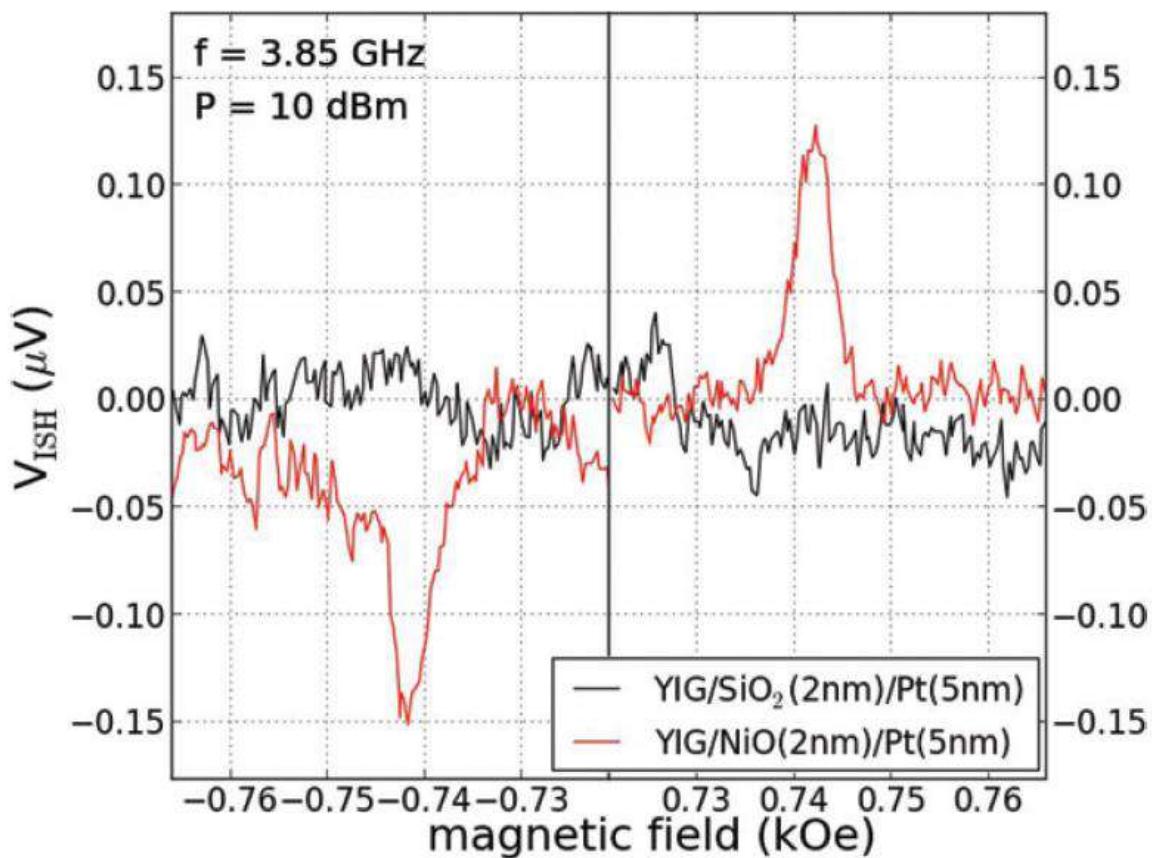
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www.epljournal.org

Conduction of spin currents through insulating antiferromagnetic oxides

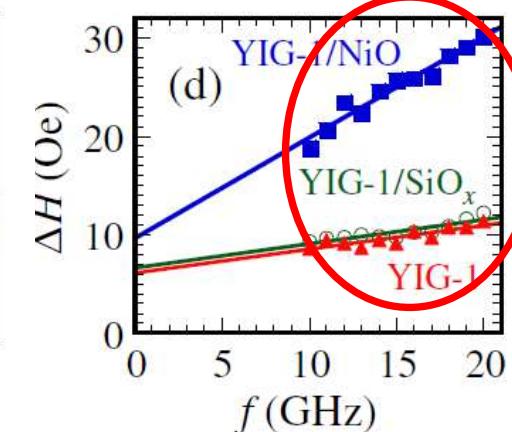
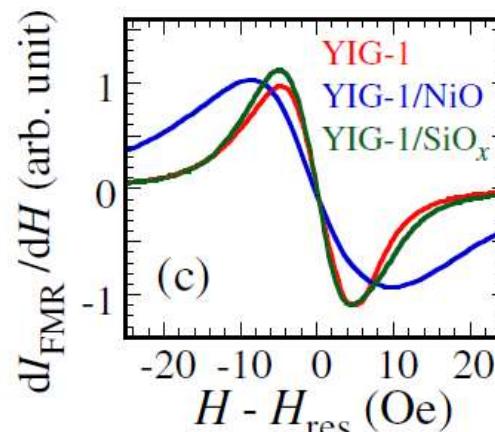
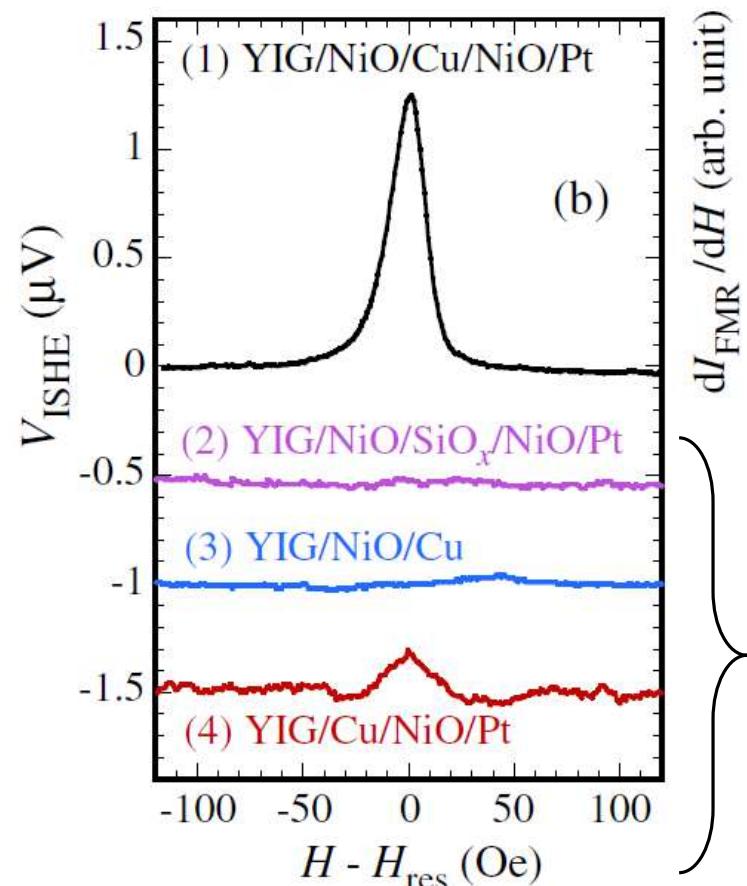


Antiferromagnetic Spin Transport from $\text{Y}_3\text{Fe}_5\text{O}_{12}$ into NiO

Hailong Wang, Chunhui Du, P. Chris Hammel,^{*} and Fengyuan Yang[†]

Department of Physics, The Ohio State University, Columbus, Ohio 43210, USA

(Received 21 March 2014; revised manuscript received 21 May 2014; published 29 August 2014)



- Increase of Gilbert damping $\left(\mu_0 \Delta H = \frac{\alpha}{\gamma} 2\pi f \right)$
- Spincurrent transported through NiO and is enhanced in case of direct YIG/NiO proximity
- Additional channel to carry away angular momentum

Spin currents and Antiferromagnets : Transport

PHYSICAL REVIEW B **93**, 224421 (2016)

Transformation of spin current by antiferromagnetic insulators

Roman Khymyn,^{1,*} Ivan Lisenkov,^{1,2} Vasil S. Tiberkevich,¹ Andrei N. Slavin,¹ and Boris A. Ivanov^{3,4}

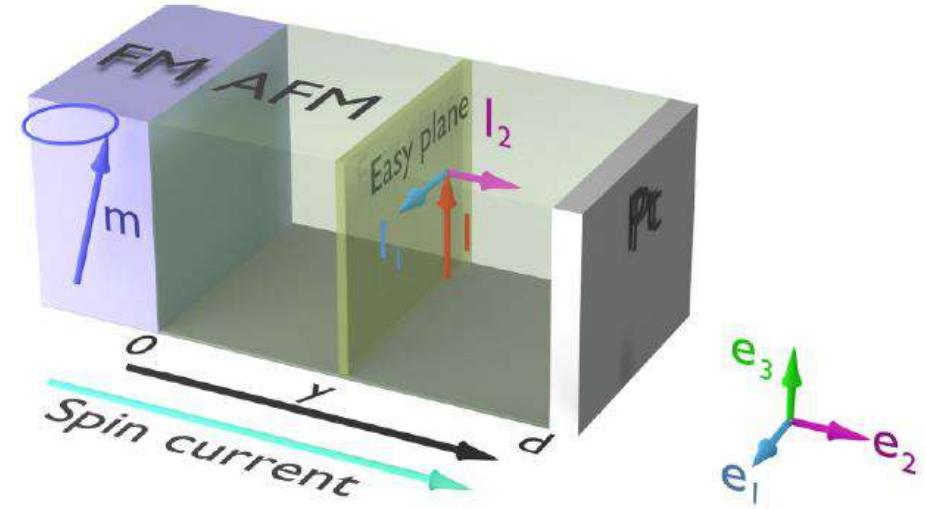
¹*Department of Physics, Oakland University, Rochester, Michigan 48309, USA*

²*Institute of Radio-engineering and Electronics of RAS, Moscow 125009, Russia*

³*Institute of Magnetism, NASU and MESYSU, Kiev 03142, Ukraine*

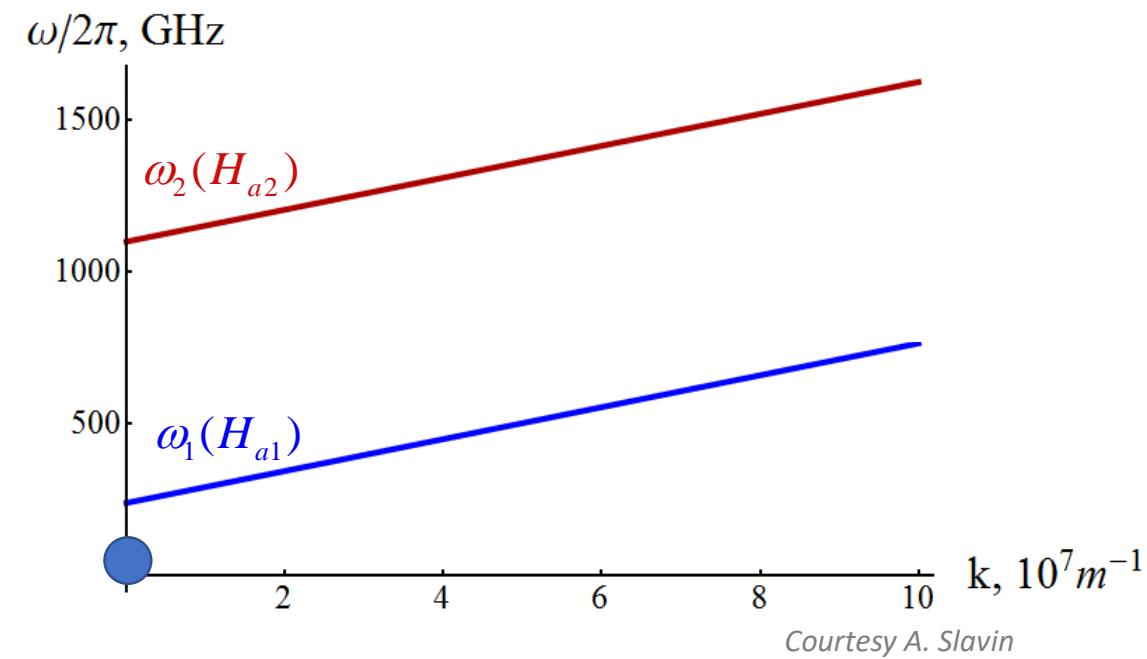
⁴*Taras Shevchenko National University of Kiev, 01601 Kiev, Ukraine*

(Received 29 November 2015; revised manuscript received 19 May 2016; published 22 June 2016)



Driven magnetization dynamics in the GHz: far below AF dynamics

- Spin current transfer cannot be explained by the excitation of AF propagating spinwaves



Courtesy A. Slavin

Spin currents and Antiferromagnets : Transport

PHYSICAL REVIEW B **93**, 224421 (2016)

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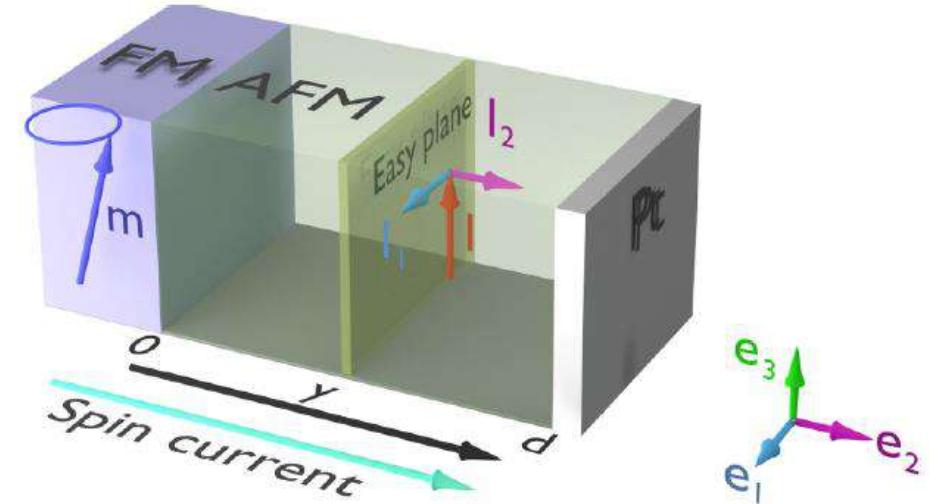
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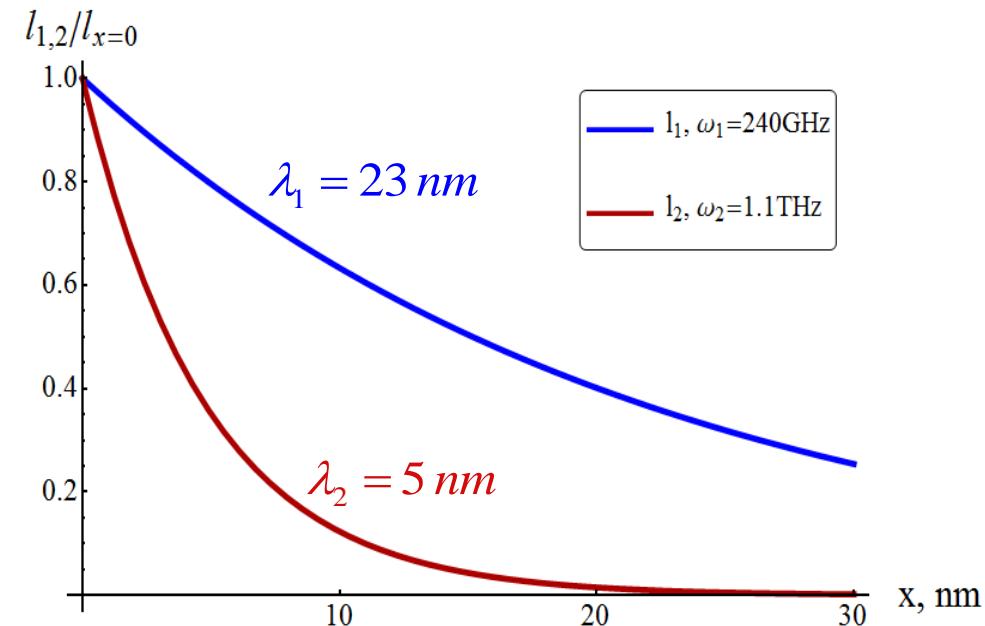


Driven magnetization dynamics in the GHz: far below AF dynamics

- Spin current transfer cannot be explained by the excitation of AF propagating spinwaves
- Ferromagnetic dynamics generates evanescent modes in the AF layer

Penetration depth:

$$\lambda_j = c / \sqrt{\omega_j^2 - \omega^2}$$



Courtesy A. Slavin

Spin currents and Antiferromagnets : Transport

PHYSICAL REVIEW B **93**, 224421 (2016)

Transformation of spin current by antiferromagnetic insulators

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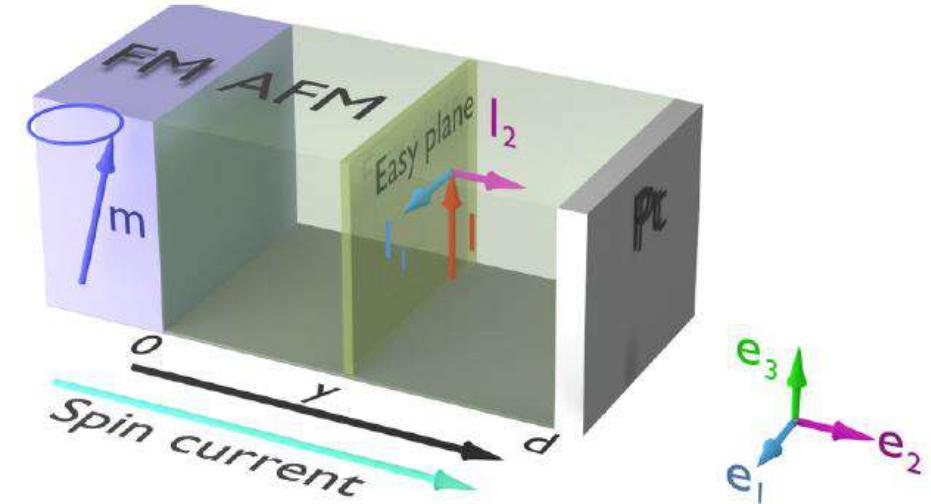
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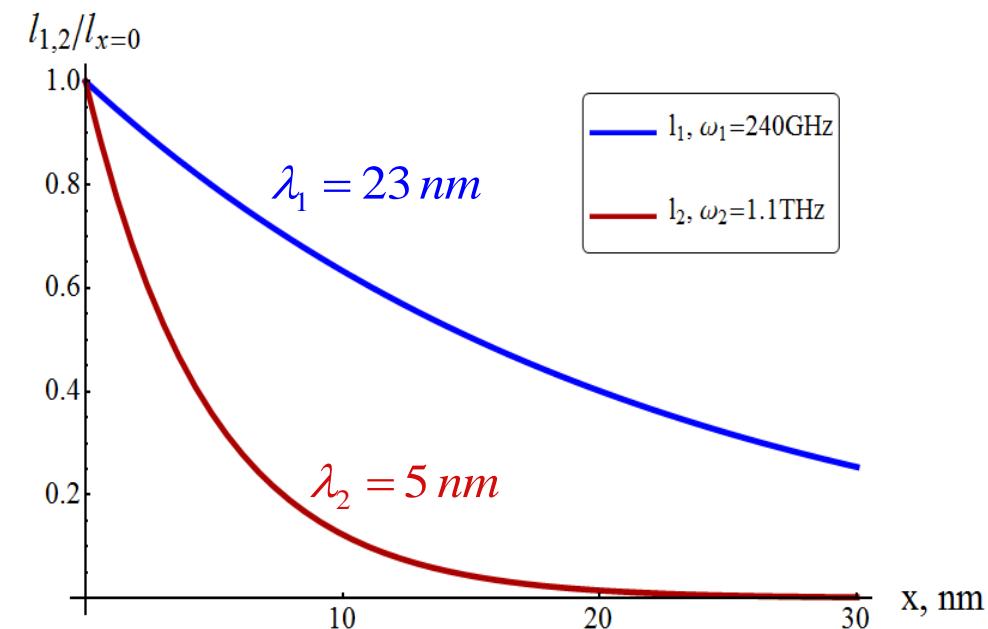
⁴*Taras Shevchenko National University of Kiev, 01601 Kiev, Ukraine*

(Received 29 November 2015; revised manuscript received 19 May 2016; published 22 June 2016)



Driven magnetization dynamics in the GHz: far below AF dynamics

- Spin current transfer cannot be explained by the excitation of AF propagating spinwaves
- Ferromagnetic dynamics generates evanescent modes in the AF layer
- Linearly polarized evanescent modes



Courtesy A. Slavin

Spin currents and Antiferromagnets : Transport

PHYSICAL REVIEW B **93**, 224421 (2016)

Transformation of spin current by antiferromagnetic insulators

Roman Khymyn,^{1,*} Ivan Lisenkov,^{1,2} Vasil S. Tiberkevich,¹ Andrei N. Slavin,¹ and Boris A. Ivanov^{3,4}

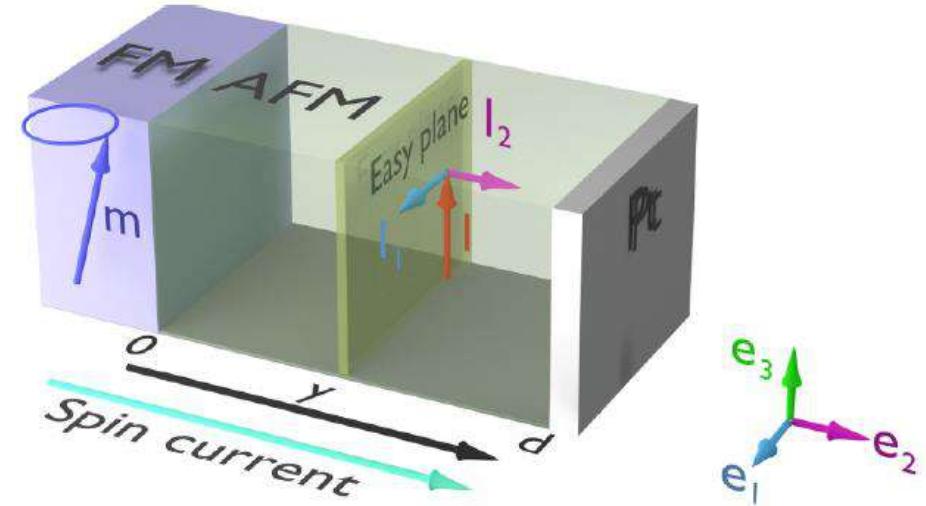
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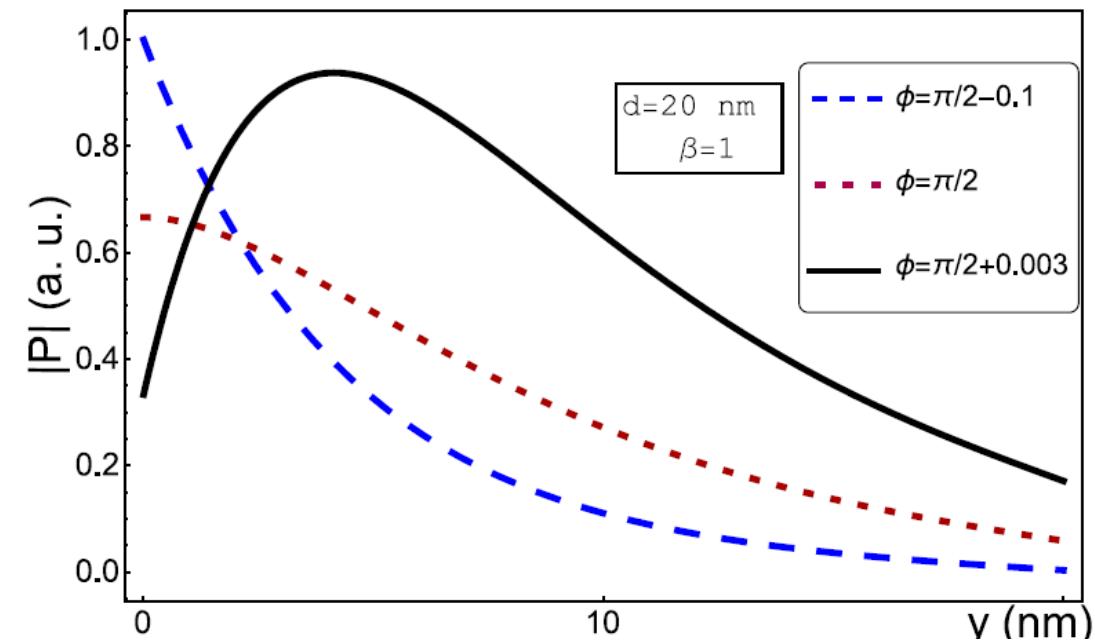
⁴*Taras Shevchenko National University of Kiev, 01601 Kiev, Ukraine*

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Driven magnetization dynamics in the GHz: far below AF dynamics

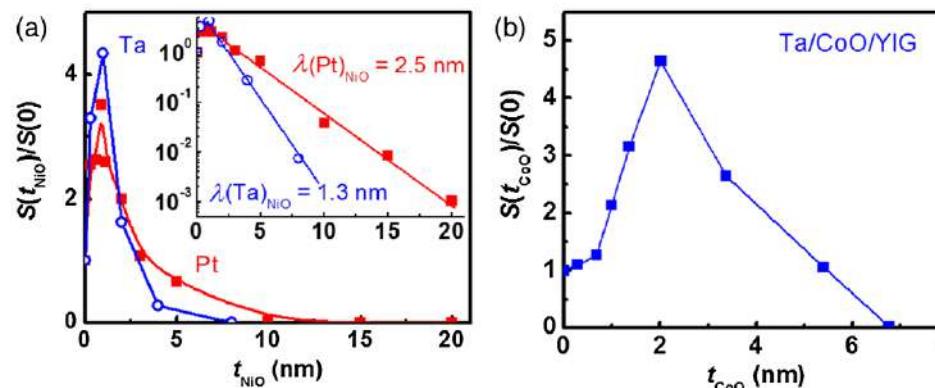
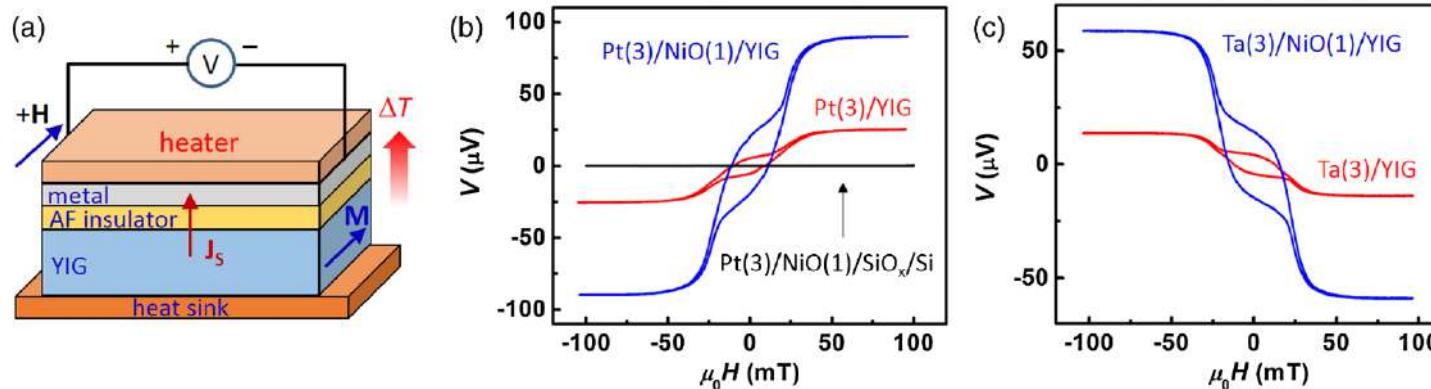
- Spin current transfer cannot be explained by the excitation of AF propagating spinwaves
- Ferromagnetic dynamics generates evanescent modes in the AF layer
- Linearly polarized evanescent modes
- 2 modes have to be both excited in order to support the angular momentum transport



Enhancement of Thermally Injected Spin Current through an Antiferromagnetic Insulator

 Weiwei Lin,^{1,*} Kai Chen,² Shufeng Zhang,² and C. L. Chien^{1,†}
¹*Department of Physics and Astronomy, Johns Hopkins University, Baltimore, Maryland 21218, USA*
²*Department of Physics, University of Arizona, Tucson, Arizona 85721, USA*

(Received 15 October 2015; revised manuscript received 8 February 2016; published 5 May 2016)

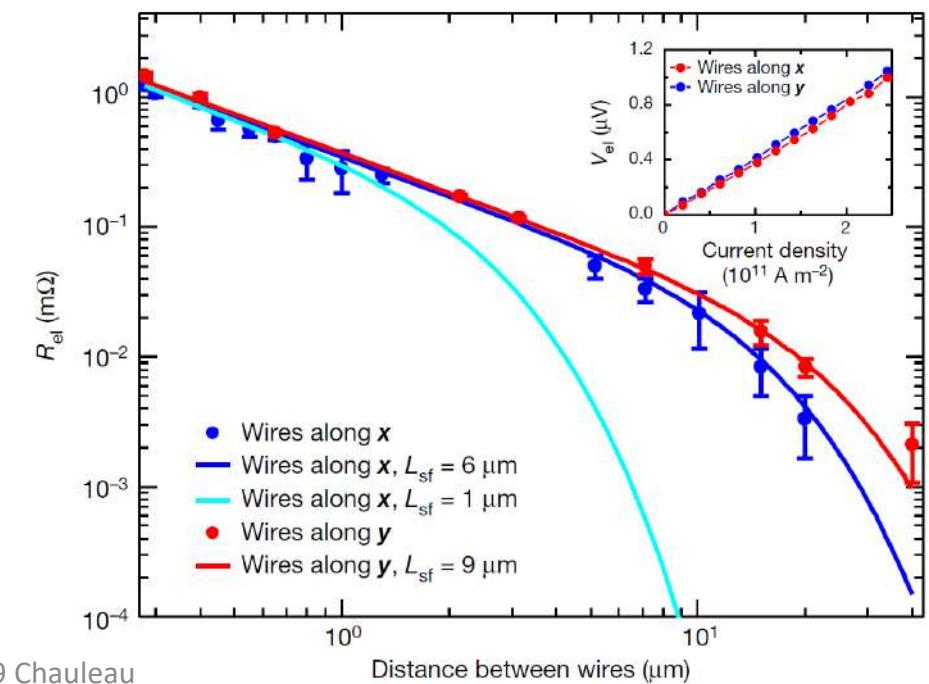
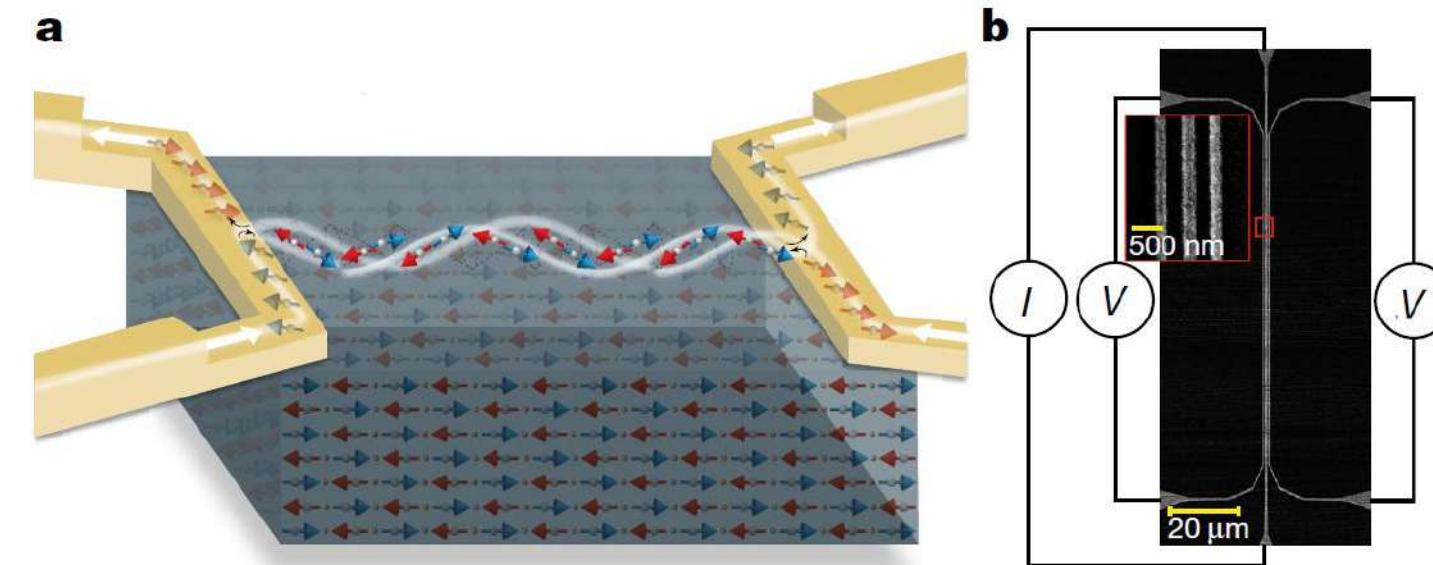


- Spincurrent driven by spin Seebeck effect
- Unlike FMR spin pumping:
DC spincurrent, no coherent resonance
- Broad spectrum distribution of non-equilibrium thermal magnons

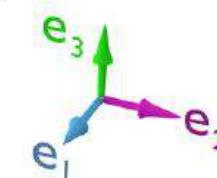
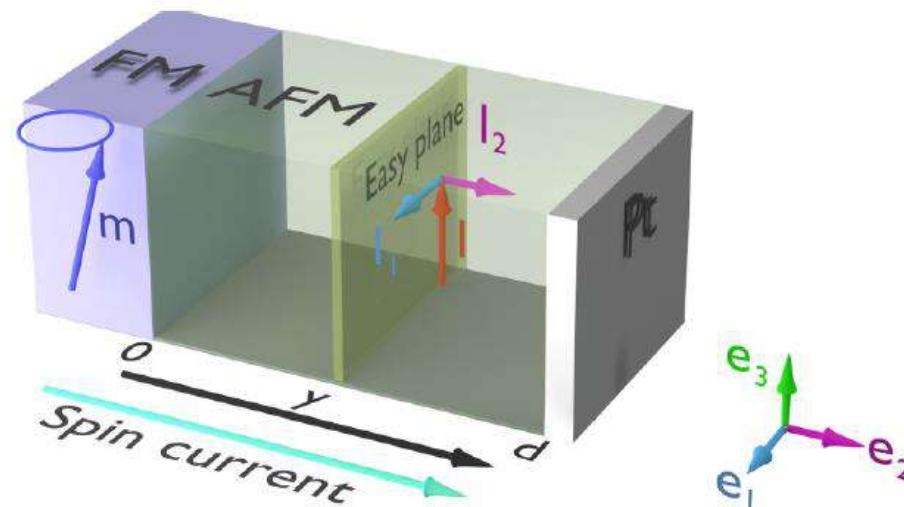
Tunable long-distance spin transport in a crystalline antiferromagnetic iron oxide

R. Lebrun^{1,6*}, A. Ross^{1,2,6}, S. A. Bender³, A. Qaiumzadeh⁴, L. Baldrati¹, J. Cramer^{1,2}, A. Brataas⁴, R. A. Duine^{3,4,5} & M. Kläui^{1,2,4*}

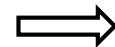
- Spincurrent in AF induced by 2 effects:
 - ✓ spin-Seebeck effect
 - ✓ spin accumulation at the Pt/AF interface
- Unlike previous studies: long-distance spincurrent transport in AF ($\alpha\text{-Fe}_2\text{O}_3$)



Spin currents and Antiferromagnets : Transport



Antiferromagnetic insulators



Low dissipation spincurrent conductors

Spin currents and Antiferromagnets : AF manipulation

What about manipulating AF distributions using spin currents?

Spin currents and Antiferromagnets : AF manipulation

PHYSICAL REVIEW B 81, 144427 (2010)

Spin transfer and current-induced switching in antiferromagnets

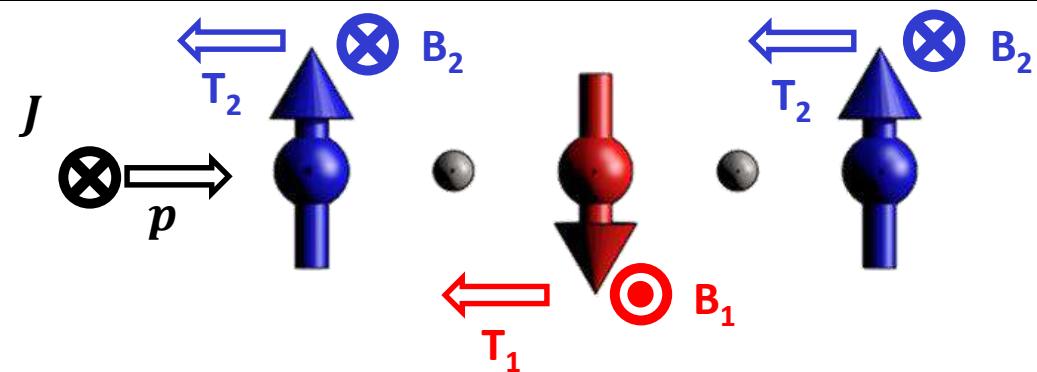
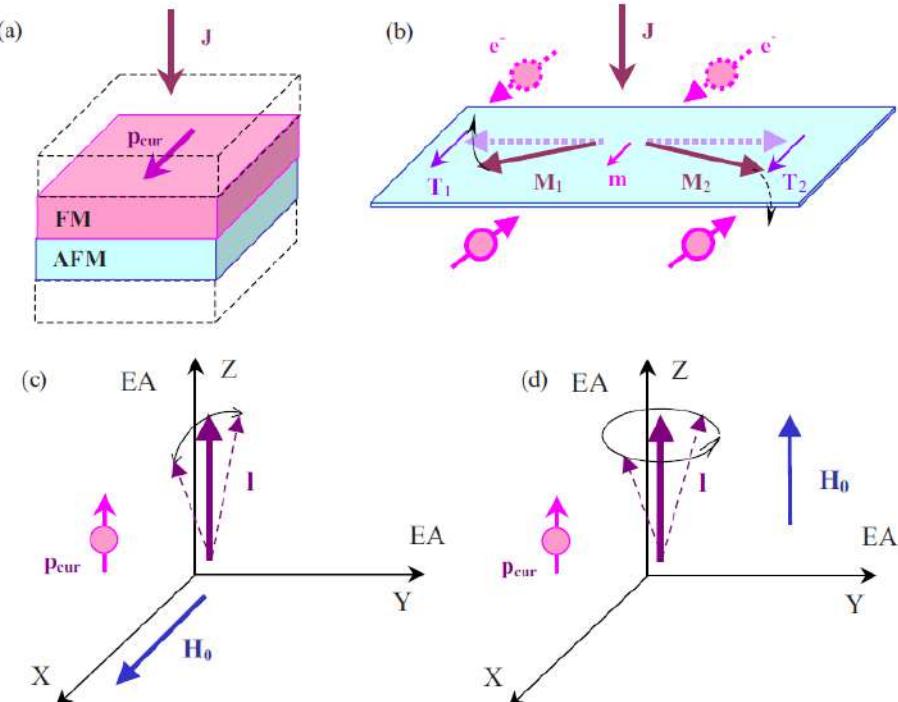
Helen V. Gomonay

National Technical University of Ukraine "KPI," 37 Peremogy Avenue, 03056 Kyiv, Ukraine

Vadim M. Loktev

Bogolyubov Institute for Theoretical Physics, NAS of Ukraine, Metrologichna Street 14-b, 03143 Kyiv, Ukraine

(Received 21 September 2009; revised manuscript received 17 December 2009; published 27 April 2010)



- Spin-polarized current can efficiently manipulate the AF order
- Spin-torque ($T_{1(2)}$) on each individual sublattices

$$\frac{d\mathbf{m}_1}{dt} = -\mu_0 \gamma \mathbf{m}_1 \times (-J \mathbf{m}_2 + \mathbf{H}_A - \mathbf{H}) + \mathbf{T}_1$$

$$\frac{d\mathbf{m}_2}{dt} = -\mu_0 \gamma \mathbf{m}_2 \times (-J \mathbf{m}_1 + \mathbf{H}_A + \mathbf{H}) + \mathbf{T}_2$$

with $\mathbf{T}_{1(2)} \propto \mathbf{m}_{1(2)} \times (\mathbf{m}_{1(2)} \times \mathbf{p})$

Eq. to a staggered "field", $B_{1(2)}$

See also:

- Gomonay et al. Phys. Rev. B 85 134446 (2012)
- Cheng et al. Phys. Rev. Lett. 113, 057601 (2014)
- Cheng et al. Phys. Rev. B 113, 064423 (2015)

Spin currents and Antiferromagnets : AF manipulation

PHYSICAL REVIEW B **91**, 064423 (2015)

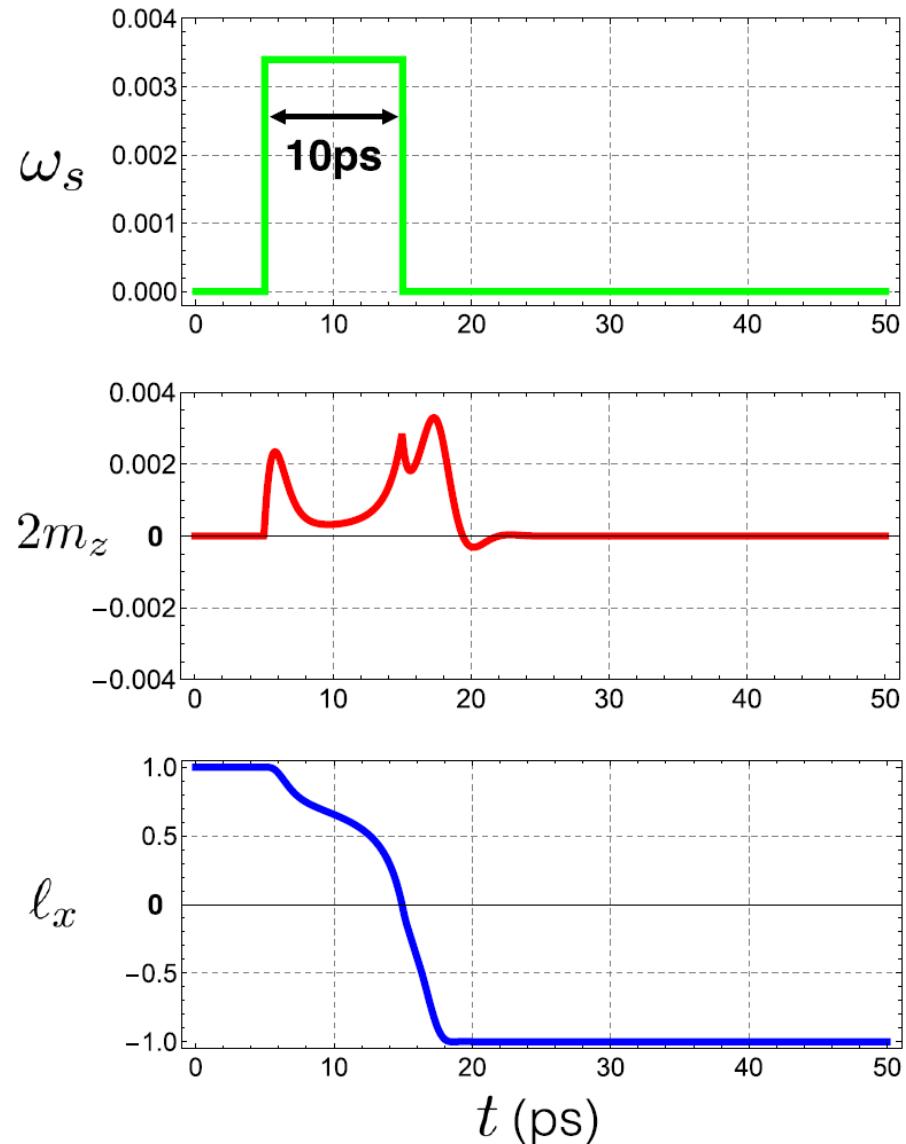
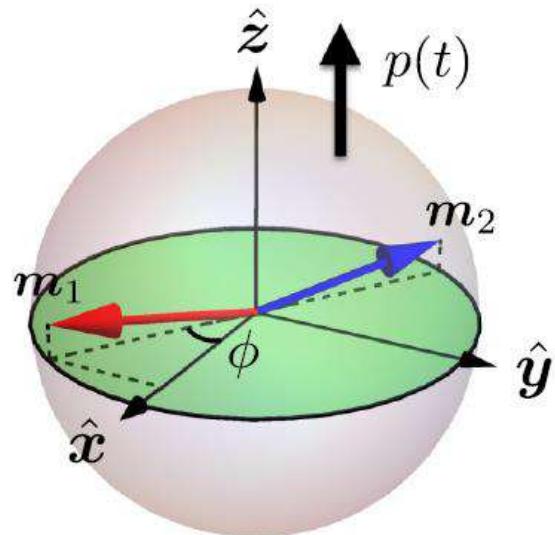
Ultrafast switching of antiferromagnets via spin-transfer torque

Ran Cheng,¹ Matthew W. Daniels,¹ Jian-Gang Zhu,² and Di Xiao¹

¹Department of Physics, Carnegie Mellon University, 5000 Forbes Avenue, Pittsburgh, Pennsylvania 15213, USA

²Department of Electrical and Computer Engineering, Carnegie Mellon University, 5000 Forbes Avenue, Pittsburgh, Pennsylvania 15213, USA

(Received 10 December 2014; published 27 February 2015)

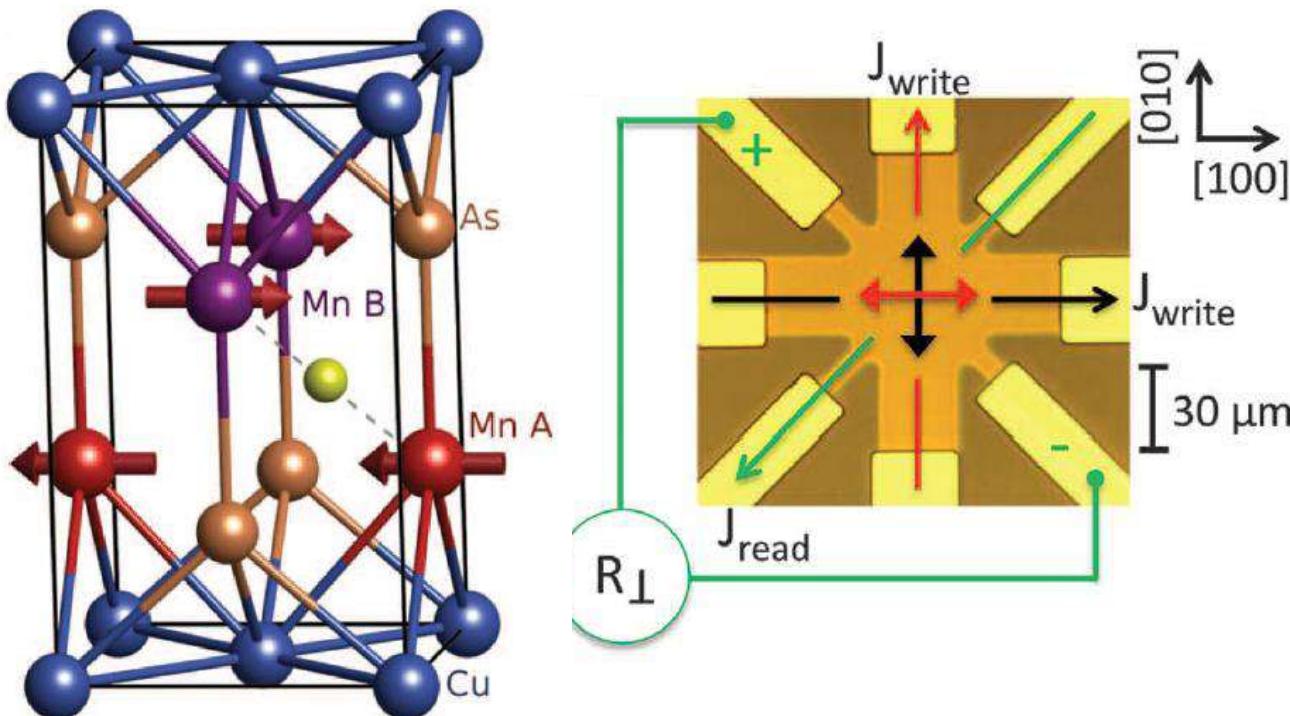


Spin currents and Antiferromagnets : AF manipulation

SPINTRONICS

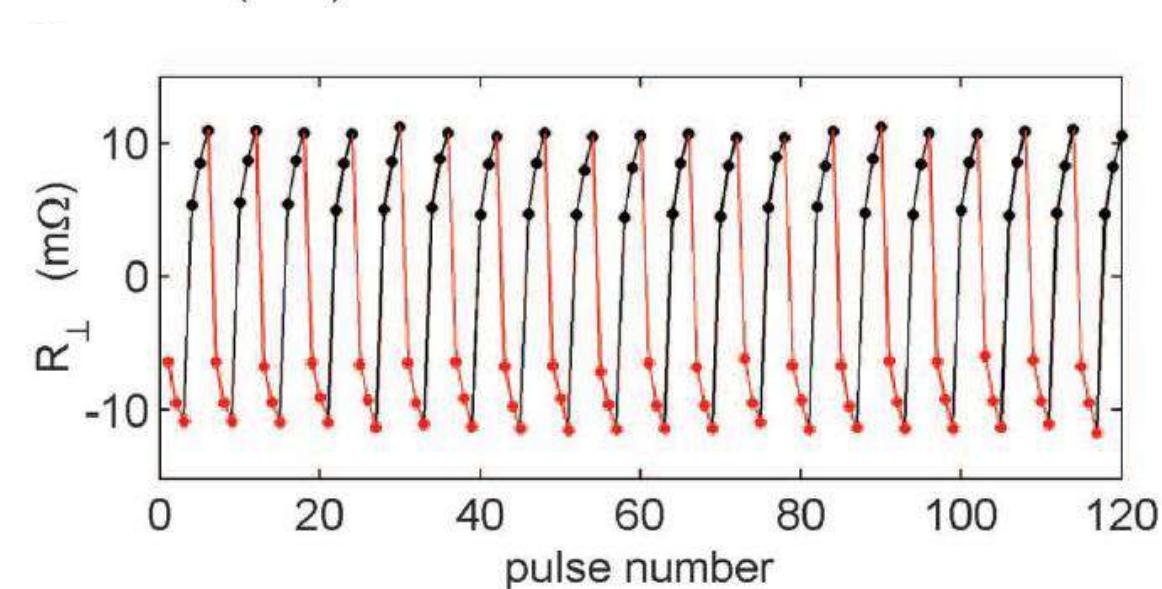
Electrical switching of an antiferromagnet

P. Wadley,^{1,*†} B. Howells,^{1,*} J. Železný,^{2,3} C. Andrews,¹ V. Hills,¹ R. P. Campion,¹ V. Novák,² K. Olejník,² F. Maccherozzi,⁴ S. S. Dhesi,⁴ S. Y. Martin,⁵ T. Wagner,^{5,6} J. Wunderlich,^{2,5} F. Freimuth,⁷ Y. Mokrousov,⁷ J. Kuneš,⁸ J. S. Chauhan,¹ M. J. Grzybowski,^{1,9} A. W. Rushforth,¹ K. W. Edmonds,¹ B. L. Gallagher,¹ T. Jungwirth^{2,1}



Antiferromagnetic Spintronics - ISOE2019 Chauleau

- First experimental demonstration in CuMnAs by Wadley et al. *SCIENCE* **351** 587 (2016)
- Local Broken inversion symmetry: electrical current generates a non-equilibrium spin-polarization with opposite polarities on sites A and B

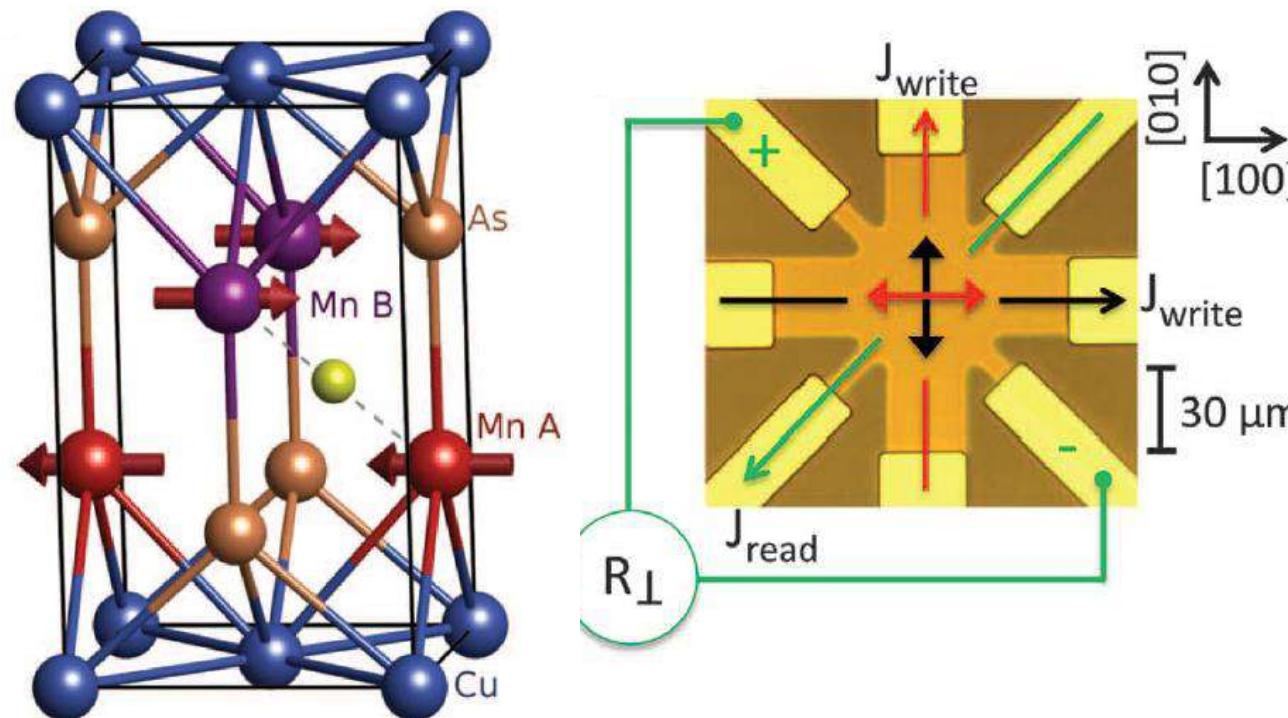


Spin currents and Antiferromagnets : AF manipulation

SPINTRONICS

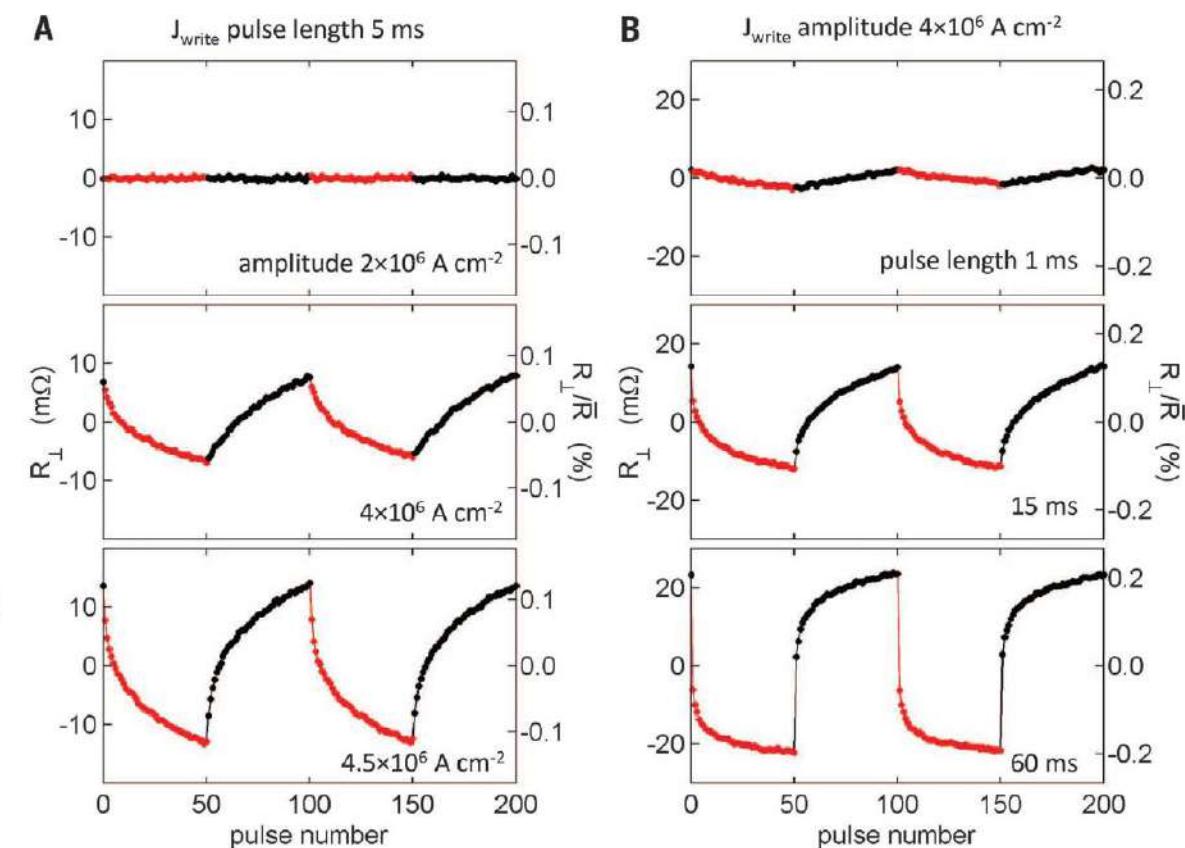
Electrical switching of an antiferromagnet

P. Wadley,^{1,*†} B. Howells,^{1,*} J. Železný,^{2,3} C. Andrews,¹ V. Hills,¹ R. P. Campion,¹ V. Novák,² K. Olejník,² F. Maccherozzi,⁴ S. S. Dhesi,⁴ S. Y. Martin,⁵ T. Wagner,^{5,6} J. Wunderlich,^{2,5} F. Freimuth,⁷ Y. Mokrousov,⁷ J. Kuneš,⁸ J. S. Chauhan,¹ M. J. Grzybowski,^{1,9} A. W. Rushforth,¹ K. W. Edmonds,¹ B. L. Gallagher,¹ T. Jungwirth^{2,1}



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Spin currents and Antiferromagnets : AF manipulation

PRL 118, 057701 (2017)

PHYSICAL REVIEW LETTERS

week ending
3 FEBRUARY 2017

Imaging Current-Induced Switching of Antiferromagnetic Domains in CuMnAs

M. J. Grzybowski,^{1,2} P. Wadley,¹ K. W. Edmonds,¹ R. Beardsley,¹ V. Hills,¹ R. P. Campion,¹ B. L. Gallagher,¹ J. S. Chauhan,¹ V. Novak,³ T. Jungwirth,^{3,1} F. Maccherozzi,⁴ and S. S. Dhesi⁴

¹School of Physics and Astronomy, University of Nottingham, University Park, Nottingham NG7 2RD, United Kingdom

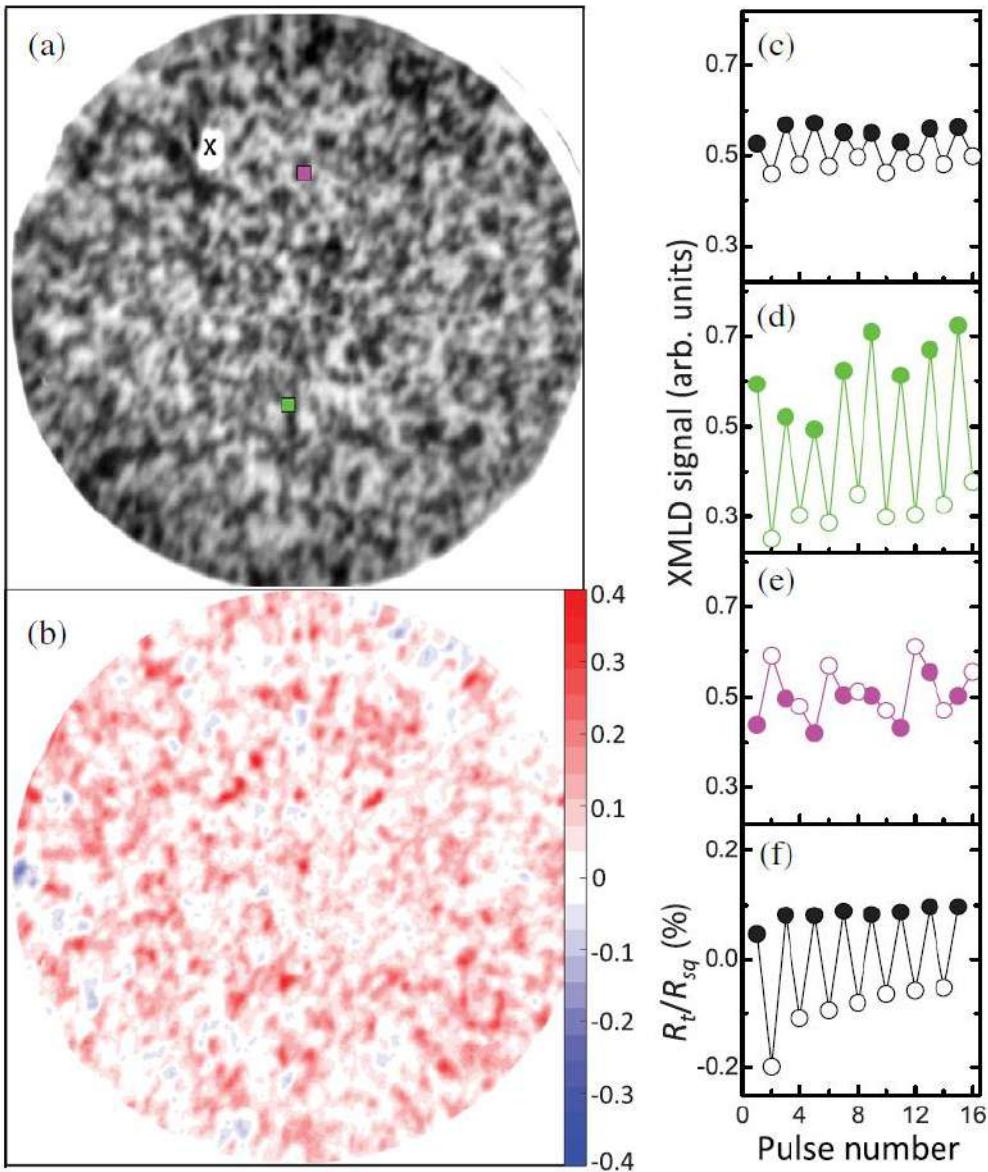
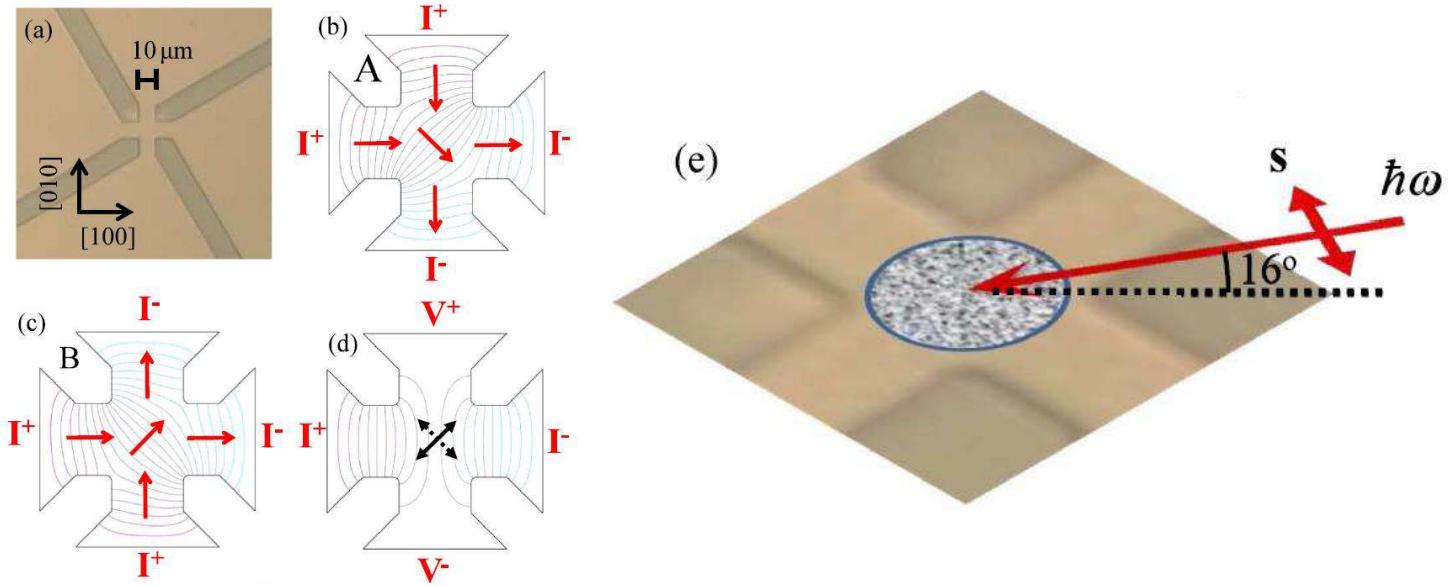
²Institute of Physics, Polish Academy of Sciences, Aleja Lotników 32/46, PL-02668 Warsaw, Poland

³Institute of Physics, Academy of Sciences of the Czech Republic, Cukrovarnická 10, 162 00 Praha 6, Czech Republic

⁴Diamond Light Source, Chilton, Didcot, Oxfordshire OX11 0DE, United Kingdom

(Received 4 August 2016; published 31 January 2017)

➤ XLMD-PEEM imaging: synchrotron-based technique sensitive to the Néel vector



Spin currents and Antiferromagnets : AF manipulation

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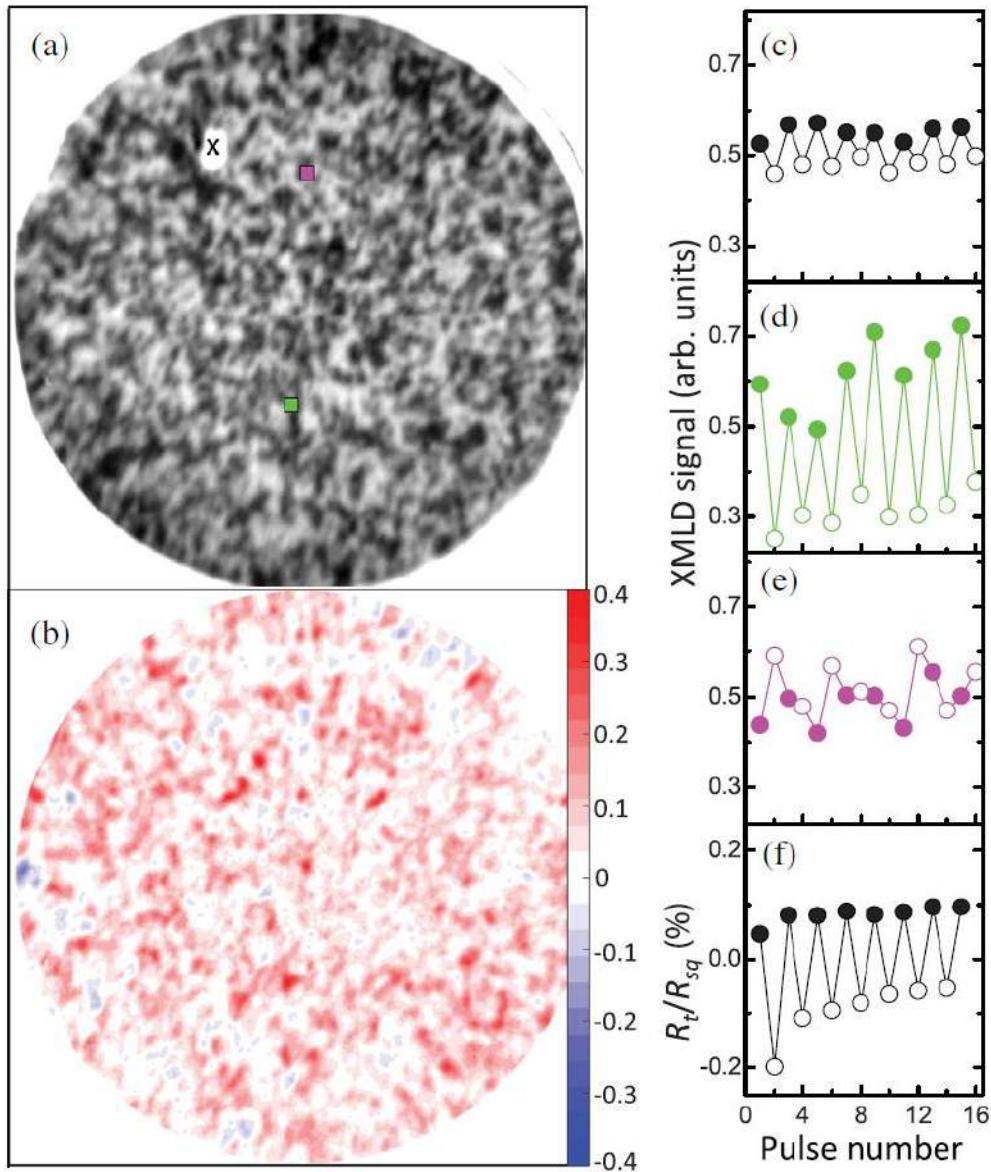
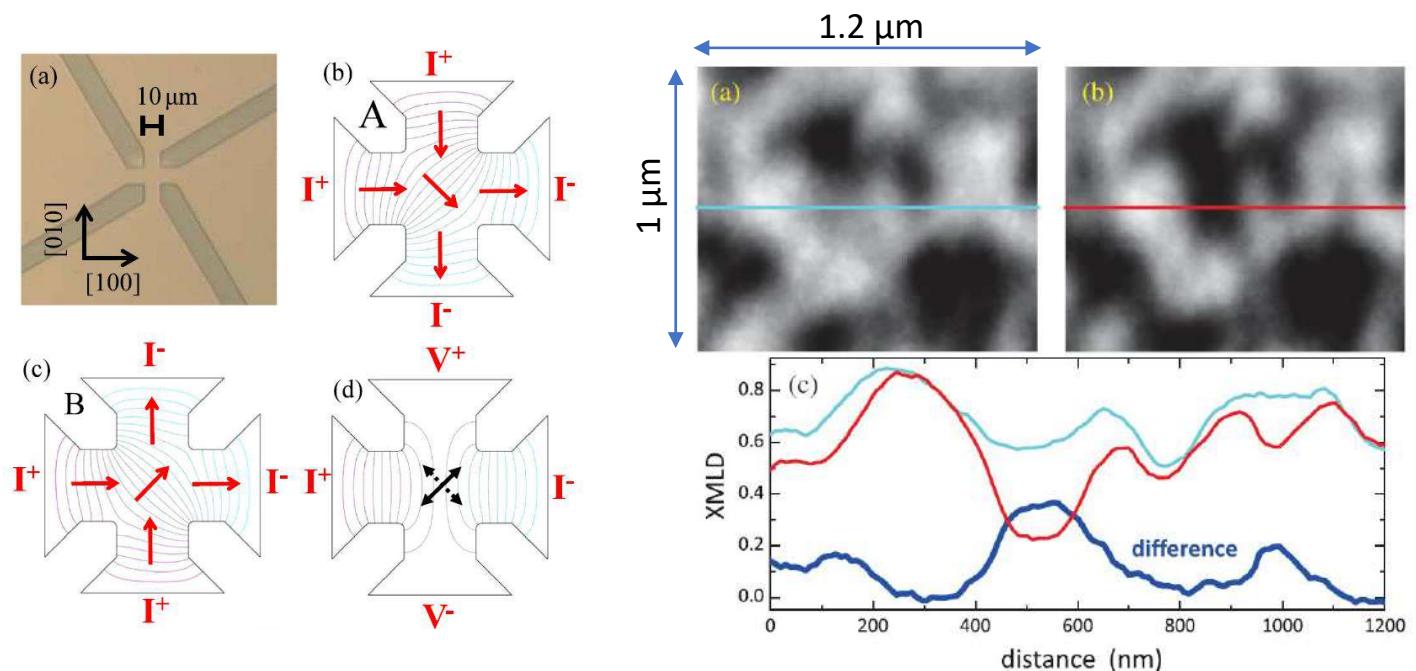
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Spin currents and Antiferromagnets : AF manipulation

Feb, 2016

October, 2016

Science paper

2 cells wire bonded

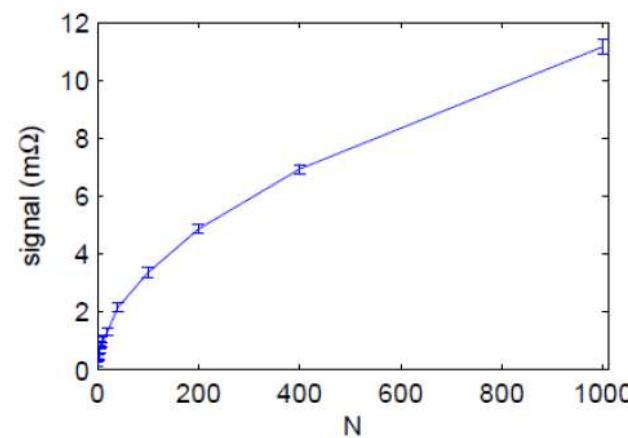
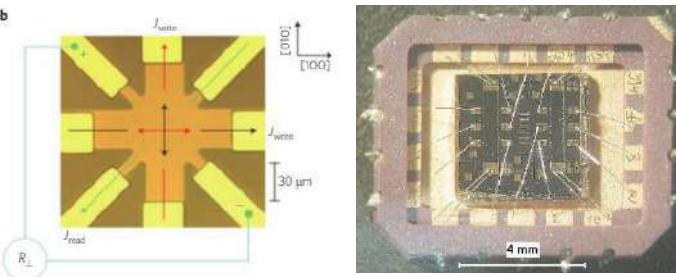
Packaged prototype

Passive traffic flow monitoring

Science
ADVERTISMENT
Cite as: P. Wadley et al., Science 351, 1256000 (2016). DOI: 10.1126/science.1256000

Electrical switching of an antiferromagnet

P. Wadley,^{1,*} B. Housden,^{1,*} J. Pešek,^{2,3} C. Antunes,² V. Hilti,² R. P. Campion,¹ V. Novák,² K. Osejník,² T. Maretzky,² S. S. Dholakia,² S. V. Martin,² T. Wagner,^{2,4} J. Wunderlich,^{2,4} F. Freudenreich,² Y. Matsumoto,^{2,5} J. Knoll,² J. S. Chandan,² M. J. Grzybowski,^{2,6} A. W. Radford,² E. W. Edmonds,² B. L. Gallagher,² T. Jungwirth,²



One AFM cell is an incremental counter

8 pin chip carrier: could contain 2 AFMEM counters
+
Transistors, USB comms, voltmeter, programming

Spin currents and Antiferromagnets : AF “ultrafast” manipulation?

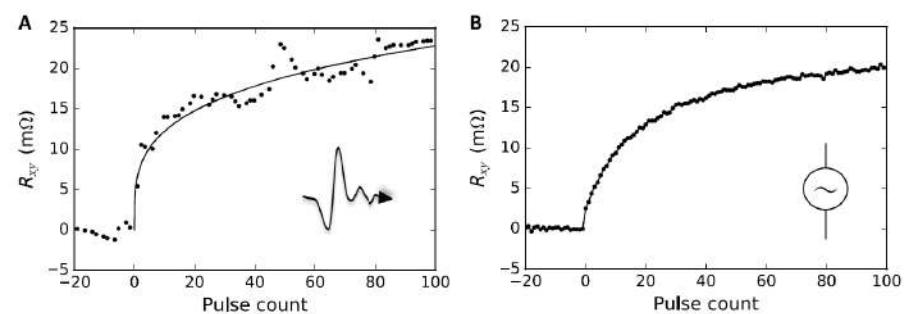
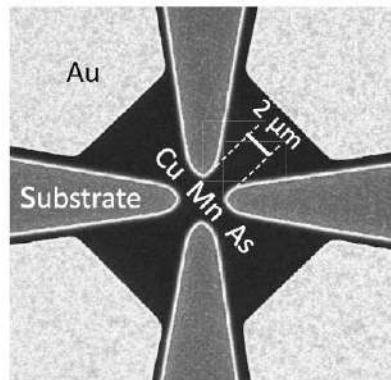
SCIENCE ADVANCES | RESEARCH ARTICLE

Sci. Adv. 2018;4: eaar3566 (2018)

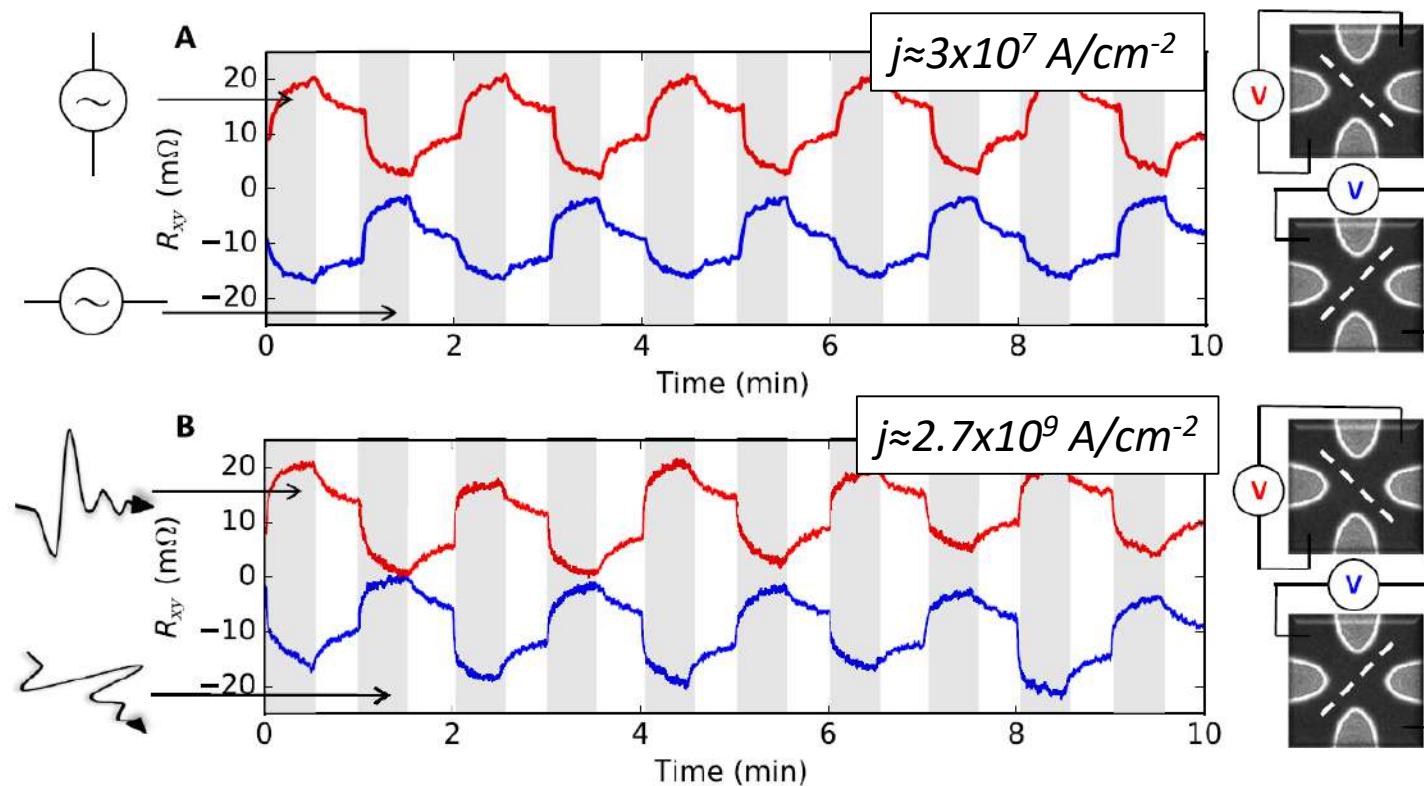
APPLIED SCIENCES AND ENGINEERING

Terahertz electrical writing speed in an antiferromagnetic memory

Kamil Olejník,^{1*} Tom Seifert,² Zdeněk Kašpar,^{1,3} Vít Novák,¹ Peter Wadley,⁴ Richard P. Campion,⁴ Manuel Baumgartner,⁵ Pietro Gambardella,⁵ Petr Němec,³ Joerg Wunderlich,^{1,6} Jairo Sinova,^{1,7} Petr Kužel,⁸ Melanie Müller,² Tobias Kampfrath,^{2,9} Tomas Jungwirth^{1,4}



- AF system responds similarly to “DC” and THz stimuli
- DC reading: no information about a possible ultra actual



Spin currents and Antiferromagnets : THz generation

PRL 116, 207603 (2016)

PHYSICAL REVIEW LETTERS

week ending
20 MAY 2016

Terahertz Antiferromagnetic Spin Hall Nano-Oscillator

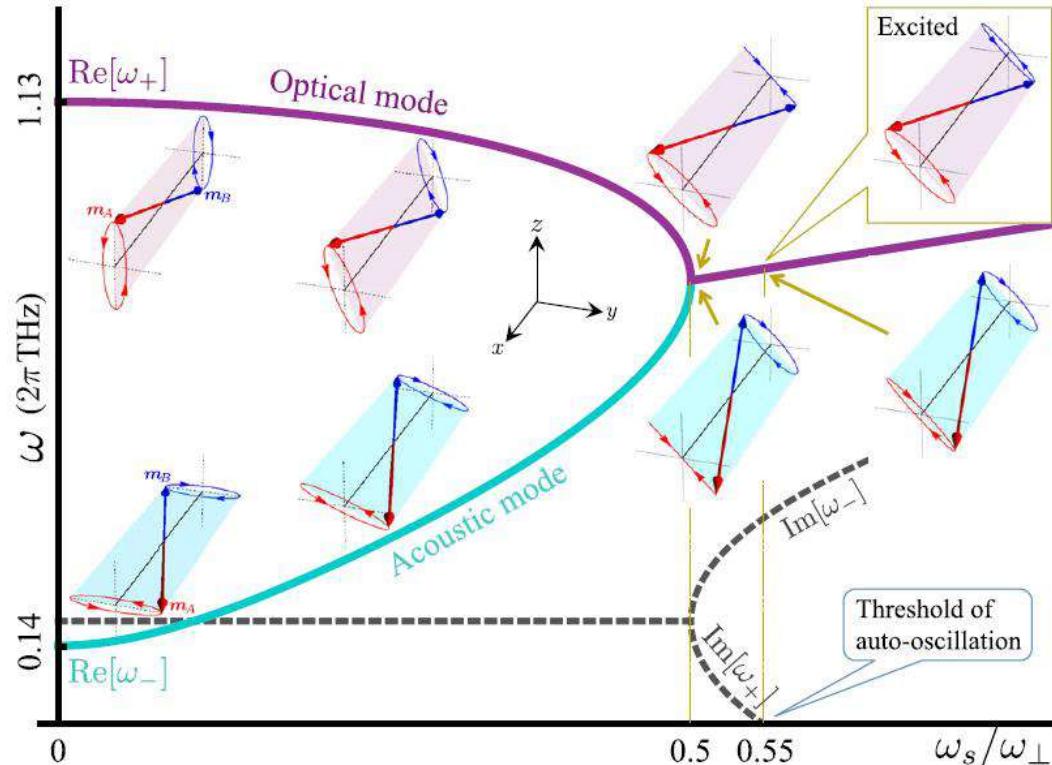
Ran Cheng^{*} and Di Xiao

Department of Physics, Carnegie Mellon University, Pittsburgh, Pennsylvania 15213, USA

Arne Brataas

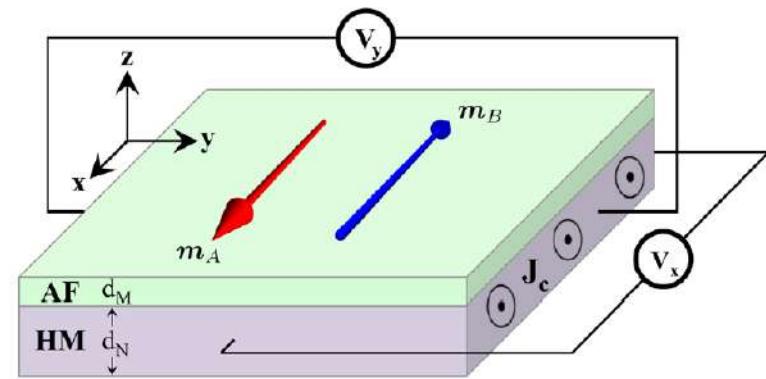
Department of Physics, Norwegian University of Science and Technology, NO-7491 Trondheim, Norway

(Received 30 September 2015; published 20 May 2016)



See also:

- Khymyn et al. Scientific report (2016)

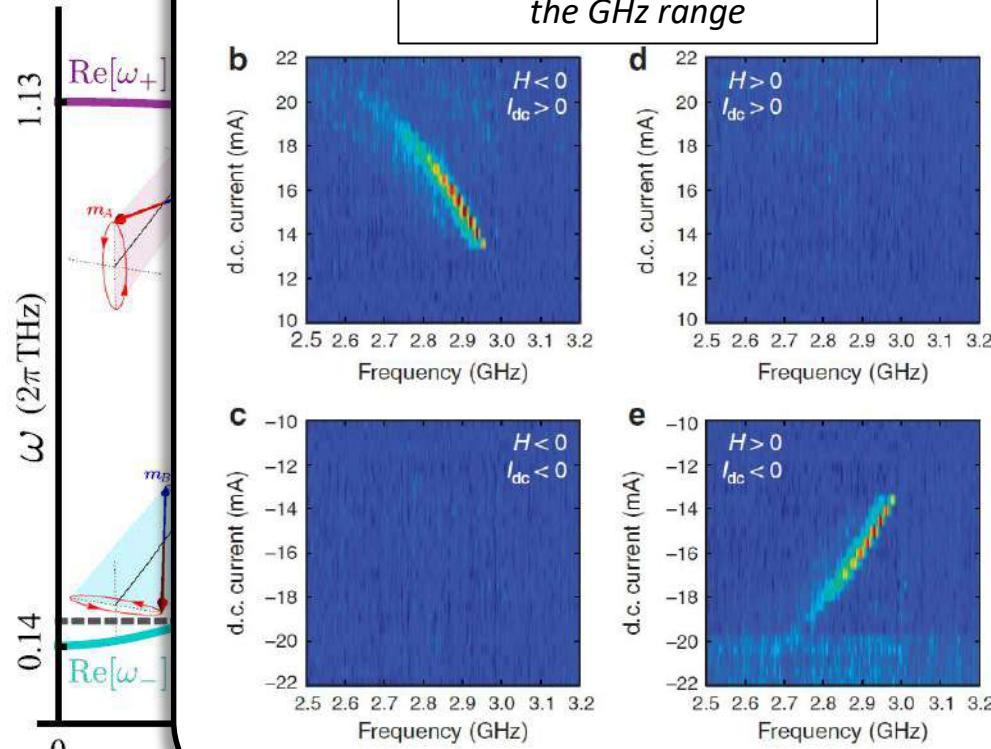


- Linear response of the AF eigenmodes as function of a DC spin-transfer torque
- At a threshold value, the STT compensate, leading to the onset of spontaneous oscillations: **auto-oscillations**

Spin currents and Antiferromagnets : THz generation

PRL 116, 207603 (2016)

Tera
Department of
Physics

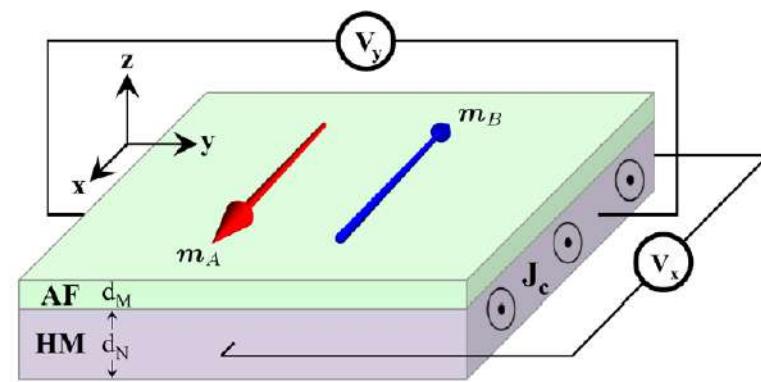


See also:

➤ Khymyn et al. Scientific report (2016)

week ending
20 MAY 2016

A
Norway



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Antiferromagnetic Spintronics - ISOE2019 Chauleau

Spin currents and Antiferromagnets : THz generation

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20 MAY 2016

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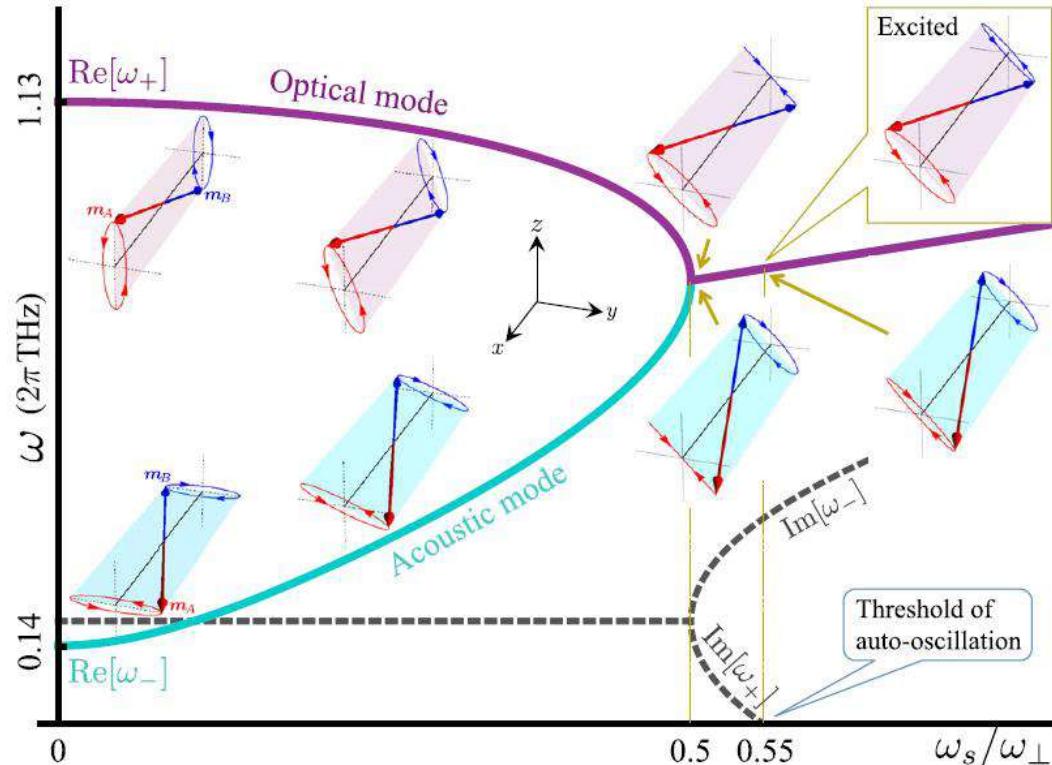
Ran Cheng^{*} and Di Xiao

Department of Physics, Carnegie Mellon University, Pittsburgh, Pennsylvania 15213, USA

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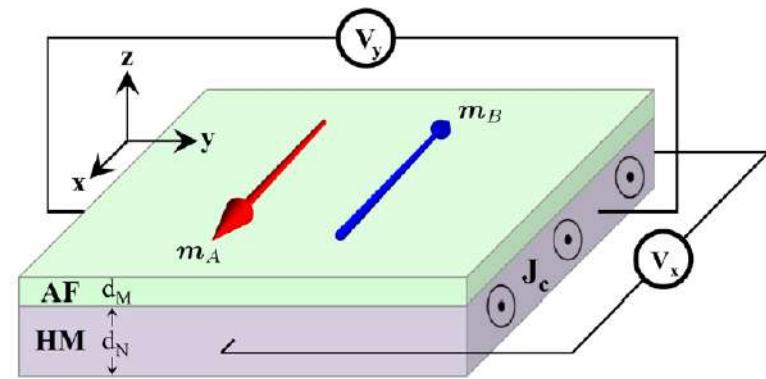
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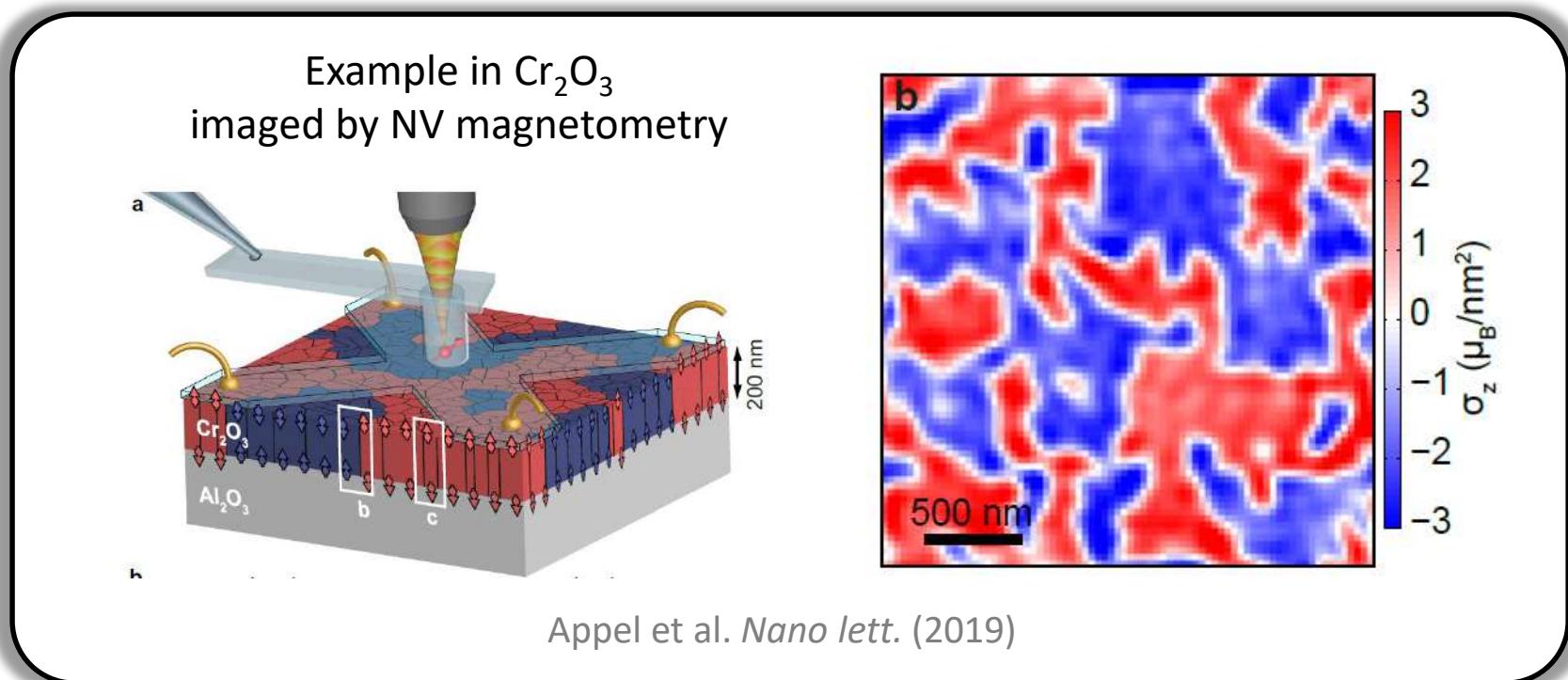


- Linear response of the AF eigenmodes as function of a DC spin-transfer torque
- At a threshold value, the STT compensate, leading to the onset of spontaneous oscillations: **auto-oscillations**
- Estimation of threshold current density for NiO/Pt systems: $j_c = 2.9 \times 10^8 \text{ A/cm}^2$
- Need to consider the “backflow”

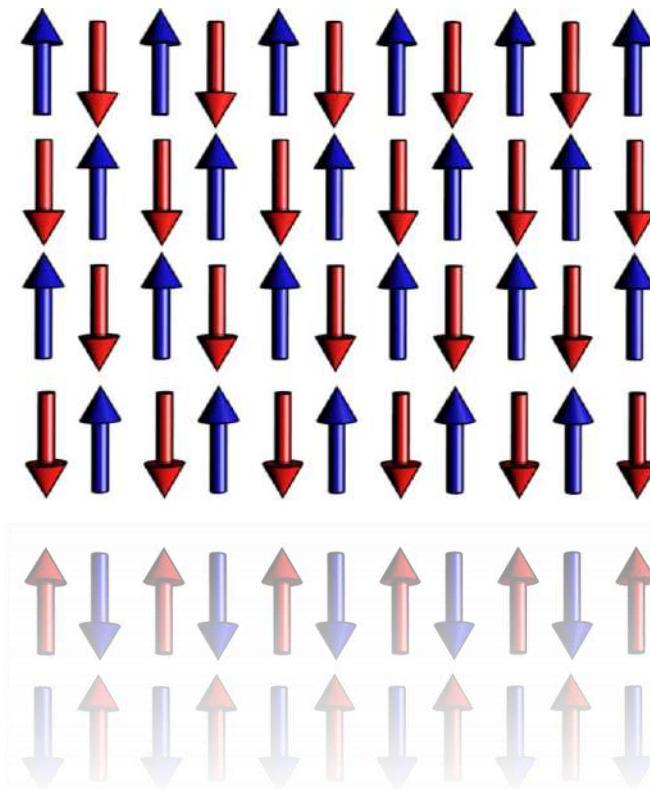
Antiferromagnetic spintronics:

One of the main challenges:

- ✓ Antiferromagnetic domains in thin layer are small
- ✓ Difficulty to prepare monodomain states



Antiferromagnetic spintronics: Conclusion



- Antiferromagnets :
 - ✓ Large majority on the magnetic materials
 - ✓ Robust against external magnetic perturbation
 - ✓ THz intrinsic dynamics
- Magnonic spincurrents can be transported through AF insulating oxides
 - ✓ Demonstrated for DC and GHz regimes
 - ✓ On long distances for bulk AF crystals
- AF order can be manipulated using spincurrents
 - ✓ Demonstrated in the peculiar case of CuMnAs
 - ✓ Several interesting theoretical works
 - ✓ Still experimentally challenging to study